











MSP430FR2522, MSP430FR2512

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MSP430FR25x2 Capacitive Touch Sensing Mixed-Signal Microcontrollers

Device Overview

1.1 **Features**

- CapTlvate™ technology capacitive touch
 - Performance
 - Fast electrode scanning with two simultaneous scans
 - Proximity sensing
 - Reliability
 - Increased immunity to power line, RF, and other environmental noise
 - Built-in spread spectrum, automatic tuning, noise filtering, and debouncing algorithms
 - Enables reliable touch solutions with 10-V RMS common-mode noise, 4-kV electrical fast transients, and 15-kV electrostatic discharge, allowing for IEC-61000-4-6, IEC-61000-4-4, and IEC-61000-4-2 compliance
 - Reduced RF emissions to simplify electrical designs
 - Support for metal touch and water rejection designs
 - Flexibility
 - Up to 8 self-capacitance and 16 mutualcapacitance electrodes
 - Mix and match self- and mutual-capacitive electrodes in the same design
 - Supports multi-touch functionality
 - Wide range of capacitance detection, wide electrode range of 0 to 300 pF
 - Low power
 - <4 μA wake-on-touch with two sensors</p>
 - Wake-on-touch state machine allows electrode scanning while CPU is asleep
 - Hardware acceleration for environmental compensation, filtering, and threshold detection
 - Ease of use
 - CapTIvate Design Center, PC GUI lets engineers design and tune capacitive buttons in real time without having to write code
 - CapTIvate software library in ROM provides ample FRAM for customer application
- Embedded microcontroller
 - 16-bit RISC architecture
 - Clock supports frequencies up to 16 MHz
 - Wide supply voltage range from 3.6 V down to 1.8 V (minimum supply voltage is restricted by SVS levels, see the SVS Specifications)

- · Optimized ultra-low-power modes
 - Active mode: 120 µA/MHz (typical)
 - Standby: <4 µA wake-on-touch with two sensors
 - Shutdown (LPM4.5): 36 nA without SVS
- Low-power ferroelectric RAM (FRAM)
 - Up to 7.5 KB of nonvolatile memory
 - Built-in error correction code (ECC)
 - Configurable write protection
 - Unified memory of program, constants, and storage
 - 10¹⁵ write cycle endurance
 - Radiation resistant and nonmagnetic
 - High FRAM-to-SRAM ratio, up to 4:1
- High-performance analog
 - Up to 8-channel 10-bit analog-to-digital converter (ADC)
 - Internal 1.5-V reference
 - Sample-and-hold 200 ksps
- · Intelligent digital peripherals
 - Two 16-bit timers with three capture/compare registers each (Timer A3)
 - One 16-bit timer associated with CapTIvate™ technology
 - One 16-bit counter-only RTC
 - 16-bit cyclic redundancy check (CRC)
- Enhanced serial communications with support for pin remap feature (see Device Comparison)
 - One eUSCI A supports UART, IrDA, and SPI
 - One eUSCI B supports SPI and I²C
- Clock system (CS)
 - on-chip 32-kHz RC oscillator (REFO)
 - on-chip 16-MHz digitally controlled oscillator (DCO) with frequency-locked loop (FLL)
 - ±1% accuracy with on-chip reference at room temperature
 - On-chip very low-frequency 10-kHz oscillator (VLO)
 - On-chip high-frequency modulation oscillator (MODOSC)
 - External 32-kHz crystal oscillator (LFXT)
 - Programmable MCLK prescalar of 1 to 128
 - SMCLK derived from MCLK with programmable prescalar of 1, 2, 4, or 8



- General input/output and pin functionality
 - Total of 15 I/Os on VQFN-20 package
 - 15 interrupt pins (P1 and P2) can wake MCU from low-power modes
- Development tools and software
 - Development tools
 - MSP CapTIvate[™] MCU development kit evaluation: use with CAPTIVATE-PGMR programmer and capacitive touch MSP430FR2522 MCU board BOOSTXL-CAPKEYPAD
 - Target development board MSP-TS430RHL20
 - Ease-of-use ecosystem
 - CapTIvate Design Center code generation, customizable GUI, real-time tuning

- 12KB ROM library includes CapTlvate touch libraries and driver libraries
- Family Members (Also See Device Characteristics)
 - MSP430FR2522: 7.25KB of program FRAM, 256B of information FRAM, 2KB of RAM up to 8 self-capacitive and 16 mutual-capacitive sensors
 - MSP430FR2512: 7.25KB of program FRAM, 256B of information FRAM, 2KB of RAM up to 4 self-capacitive or mutual-capacitive sensors
- Package options
 - 20-pin: VQFN (RHL)
 - 16-pin: TSSOP (PW)

1.2 Applications

- Electronic smart locks, door keypads, and readers
- · Garage door systems
- Intrusion HMI keypads and control panels
- · Elevator call buttons
- · Personal electronics
- Wireless speakers and headsets

- A/V receivers
- Appliances
- Power tools
- Light switches
- Video doorbells

1.3 Description

The MSP430FR25x2 is a family of ultra-low-power MSP430™ microcontrollers (MCUs) for capacitive touch sensing that feature CapTlvate™ touch technology for cost-sensitive applications featuring 1 to 16 capacitive buttons or proximity sensing. The MSP430FR25x2 MCUs offer value and performance for industrial applications exposed to electromagnetic disturbances, oil, water, and grease. The devices offer IEC-certified solutions with 5x lower power consumption than competition and support proximity sensing as well as touch through glass, plastic, and metal overlays.

TI capacitive touch sensing MSP430 MCUs are supported by an extensive hardware and software ecosystem with reference designs and code examples to get your design started quickly. The BOOSTXL-CAPKEYPAD BoosterPack™ plug-in module can be used with the CAPTIVATE-PGMR programmer board (standalone or as part of the MSP-CAPT-FR2633 CapTIvate development kit) or with the LaunchPad development kit ecosystem. TI also provides free software including the CapTIvate Design Center, where engineers can quickly develop applications with an easy-to-use GUI and MSP430Ware™ software, and comprehensive documentation with the CapTIvate technology quide.

MSP430 MCUs with CapTIvate technology provide the most integrated and autonomous capacitive-touch solutions in the market with high reliability and noise immunity at the lowest power. For more information visit ti.com/captivate.

For complete module descriptions, see the MSP430FR4xx and MSP430FR2xx Family User's Guide.



Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (2)
MSP430FR2522IPW16	TSSOP (16)	5 mm × 4.4 mm
MSP430FR2522IRHL	VQFN (20)	4.5 mm × 3.5 mm
MSP430FR2512IPW16	TSSOP (16)	5 mm × 4.4 mm
MSP430FR2512IRHL	VQFN (20)	4.5 mm × 3.5 mm

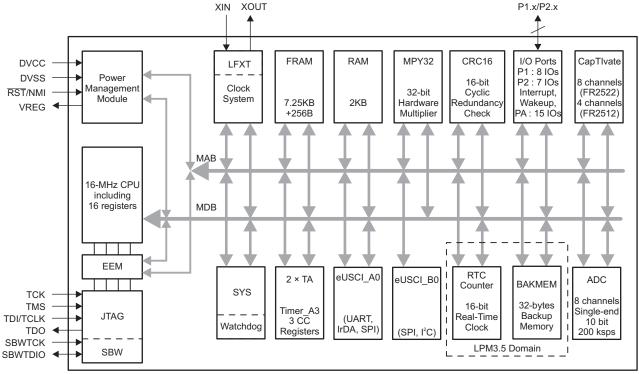
- (1) For the most current part, package, and ordering information, see the *Package Option Addendum* in Section 9, or see the TI website at www.ti.com.
- (2) The sizes shown here are approximations. For the package dimensions with tolerances, see the *Mechanical Data* in Section 9.

CAUTION

System-level ESD protection must be applied in compliance with the device-level ESD specification to prevent electrical overstress or disturbing of data or code memory. See *MSP430 System-Level ESD Considerations* for more information.

1.4 Functional Block Diagram

Figure 1-1 shows the functional block diagram.



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Figure 1-1. Functional Block Diagram

- The MCU has one main power pair of DVCC and DVSS that supplies digital and analog modules. Recommended bypass and decoupling capacitors are 4.7 μF to 10 μF and 0.1 μF, respectively, with ±5% accuracy.
- VREG is the decoupling capacitor of the CapTlvate regulator. The recommended value for the required decoupling capacitor is 1 μF, with a maximum ESR of ≤200 mΩ.
- P1 and P2 feature the pin interrupt function and can wake the MCU from all LPMs, including LPM3.5 and LPM4.
- Each Timer_A3 has three capture/compare registers. Only CCR1 and CCR2 are externally connected.
 CCR0 registers can be used only for internal period timing and interrupt generation.
- In LPM3 or LPM4 mode, the CapTIvate module can be functional while the rest of the peripherals are
 off.



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2 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from revision A to revision B

hanges from November 8, 2018 to August 19, 2019 Page
 Updated Section 1.1, Features Changed CapTIvate BSWP demonstration board to CapTIvate phone demonstration board in note (11) on Section 5.7, Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{CC}) Excluding External Current Changed CapTIvate BSWP demonstration board to CapTIvate phone demonstration board in note (19) on Section 5.7, Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{CC}) Excluding External Current Moved C_{REG} and C_{ELECTRODE} from Section 5.3, Recommended Operating Conditions to Table 5-23, CapTIvate Electrical Characteristics Added test condition for C_{ELECTRODE} in Table 5-23, CapTIvate Electrical Characteristics Changed the symbol and description of the DC_{CAPCLK} parameter in Table 5-23, CapTIvate Electrical Characteristics Moved the SNR parameter to Table 5-24, CapTIvate Signal-to-Noise Ratio Characteristics Updated Section 7.2.2, CapTIvate Peripheral Updated Section 8.2, Device Nomenclature
Changes from initial release to revision A
hanges from January 12, 2018 to November 7, 2018 Page
 Removed "15-cm" from the "Proximity Sensing" item in Section 1.1, Features Changed list item "Wide supply voltage range from 3.6 V down to 1.8 V" in Section 1.1, Features Updated Section 3.1, Related Products Changed HBM limit to ±1000 V and CDM limit to ±250 V in Section 5.2, ESD Ratings Changed the MIN value of the V_{CC} parameter from 2 V to 1.8 V in Section 5.3, Recommended Operating Conditions
 Changed the crystal in the footnote that begins "Characterized with a Seiko Crystal SC-32S crystal" in Section 5.7, Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{CC}) Excluding External Current. Changed the crystal in the footnote that begins "Characterized with a Seiko Crystal SC-32S crystal" in Section 5.8, Low-Power Mode (LPMx.5) Supply Currents (Into V_{CC}) Excluding External Current Added note on V_{SVSH}, and V_{SVSH}, parameters to Table 5-2, PMM, SVS and BOR Changed the minimum V_{CC} from 2.0 V to 1.8 V in the test conditions for the f_{REFO}, df_{REFO}/ d_{VCC}, and f_{DC}
parameters and in note (2) in Table 5-7, <i>REFO</i>
 Added the SNR parameter in Table 5-23, CapTIvate Electrical Characteristics Corrected bitfield from RTCCLK to RTCCKSEL in table note that starts "Controlled by" in Table 6-8, Clock Distribution Corrected bitfield from IRDSEL to IRDSSEL in Section 6.10.8, Timers (Timer0_A3, Timer1_A3), in the
description that starts "The interconnection of Timer0_A3 and"

www.ti.com

3 Device Comparison

Table 3-1 summarizes the features of the available family members.

Table 3-1. Device Comparison⁽¹⁾⁽²⁾

DEVICE	PROGRAM FRAM + INFORMATION FRAM (bytes)	SRAM (bytes)	TA0,TA1	eUSCI_A	eUSCI_B	10-BIT ADC CHANNELS	CapTlvate™ CHANNELS	GPIOs	PACKAGE
MSP430FR2522IRHL	7424 + 256	2048	2, 3 × CCR ⁽³⁾	1	1	8	8	15	20 RHL (VQFN)
MSP430FR2522IPW16	7424 + 256	2048	2, 3 × CCR ⁽³⁾	1	1	5	8	11	16 PW (TSSOP)
MSP430FR2512IRHL	7424 + 256	2048	2, 3 × CCR ⁽³⁾	1	1	8	4	15	20 RHL (VQFN)
MSP430FR2512IPW16	7424 + 256	2048	2, 3 × CCR ⁽³⁾	1	1	5	4	11	16 PW (TSSOP)

⁽¹⁾ For the most current package and ordering information, see the *Package Option Addendum* in Section 9, or see the TI website at www.ti.com

3.1 Related Products

For information about other devices in this family of products or related products, see the following links.

TI 16-bit and 32-bit microcontrollers

High-performance, low-power solutions to enable the autonomous future

Products for MSP430 ultra-low-power sensing and measurement microcontrollers

One platform. One ecosystem. Endless possibilities.

Companion Products for MSP430FR2522

Review products that are frequently purchased or used in conjunction with this product.

Reference Designs

Find reference designs leveraging the best in TI technology to solve your system-level challenges

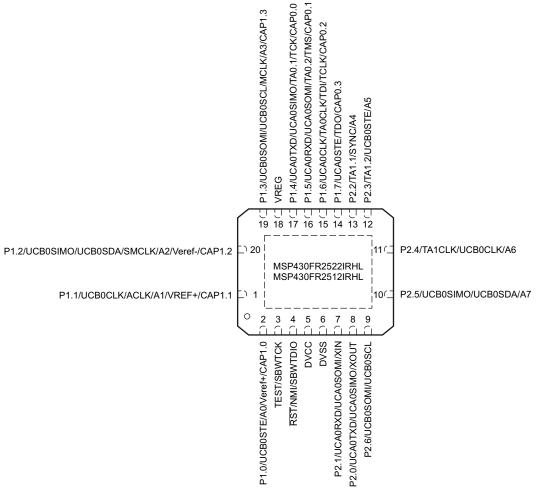
⁽²⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/packaging

⁽³⁾ A CCR register is a configurable register that provides internal and external capture or compare inputs, or internal and external PWM outputs.

4 Terminal Configuration and Functions

4.1 Pin Diagrams

Figure 4-1 shows the pinout for the 20-pin RHL package.

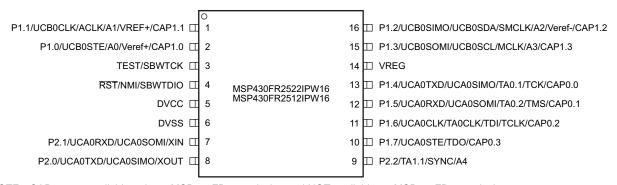


NOTE: CAP1.x are available only on MSP430FR2522 device and NOT available on MSP430FR2512 device.

Figure 4-1. 20-Pin RHL Package (Top View)



Figure 4-2 shows the pinout for the 16-pin PW package.



NOTE: CAP1.x are available only on MSP430FR2522 device and NOT available on MSP430FR2512 device.

Figure 4-2. 16-Pin PW Package (Top View)



4.2 **Pin Attributes**

Table 4-1 lists the attributes of all pins.

Table 4-1. Pin Attributes

PIN NUMBER RHL PW16		(4) (2)	SIGNAL	(4)	(5)	RESET STATE
		SIGNAL NAME ⁽¹⁾ (2)	TYPE ⁽³⁾	BUFFER TYPE ⁽⁴⁾	POWER SOURCE ⁽⁵⁾	AFTER BOR (6)
		P1.1 (RD)	I/O	LVCMOS	DVCC	OFF
		UCB0CLK	I/O	LVCMOS	DVCC	_
	_	ACLK	I/O	LVCMOS	DVCC	_
1	1	CAP1.1 ⁽⁷⁾	I/O	Analog	V_{REG}	-
		A1	1	Analog	DVCC	-
		VREF+	1	Analog	Power	-
		P1.0 (RD)	I/O	LVCMOS	DVCC	OFF
		UCB0STE	I/O	LVCMOS	DVCC	_
2	2	CAP1.0 ⁽⁷⁾	I/O	Analog	V_{REG}	_
		A0	1	Analog	DVCC	-
		Veref+	1	Analog	Power	-
		TEST (RD)	1	LVCMOS	DVCC	OFF
3	3	SBWTCK	1	LVCMOS	DVCC	_
	4	RST (RD)	1	LVCMOS	DVCC	OFF
4		NMI	1	LVCMOS	DVCC	_
		SBWTDIO	I/O	LVCMOS	DVCC	-
5	5	DVCC	Р	Power	DVCC	N/A
6	6	DVSS	Р	Power	DVCC	N/A
	7	P2.1 (RD)	I/O	LVCMOS	DVCC	OFF
7		UCA0RXD	1	LVCMOS	DVCC	_
/		UCA0SOMI	I/O	LVCMOS	DVCC	-
		XIN	1	LVCMOS	DVCC	-
		P2.0 (RD)	I/O	LVCMOS	DVCC	OFF
8	8	UCA0TXD	0	LVCMOS	DVCC	_
0	0	UCA0SIMO	I/O	LVCMOS	DVCC	_
		XOUT	0	LVCMOS	DVCC	_
		P2.6 (RD)	I/O	LVCMOS	DVCC	OFF
9	_	UCB0SOMI	I/O	LVCMOS	DVCC	_
		UCB0SCL	I/O	LVCMOS	DVCC	_
		P2.5 (RD)	I/O	LVCMOS	DVCC	OFF
10	_	UCB0SIMO	I/O	LVCMOS	DVCC	_
10	_	UCB0SDA	I/O	LVCMOS	DVCC	_
		A7	1	Analog	DVCC	_
		P2.4 (RD)	I/O	LVCMOS	DVCC	OFF
11		TA1CLK	1	LVCMOS	DVCC	_
''	_	UCB0CLK	I/O	LVCMOS	DVCC	_
		A6	I	Analog	DVCC	_

⁽¹⁾ Signals names with (RD) denote the reset default pin name.

To determine the pin mux encodings for each pin, see Section 6.11.

Signal Types: I = Input, O = Output, I/O = Input or Output

⁽⁴⁾ Buffer Types: LVCMOS, Analog, or Power (see Table 4-3)

The power source shown in this table is the I/O power source, which may differ from the module power source.

Reset States:

OFF = High-impedance with Schmitt trigger and pullup or pulldown (if available) disabled N/A = Not applicable

MSP430FR2522 only (7)



Table 4-1. Pin Attributes (continued)

PIN NUMBER		SIGNAL NAME(1) (2)	SIGNAL	DUEEED TYPE (4)	DOWED COURCE(5)	RESET STATE	
RHL	PW16	SIGNAL NAME (17 (-7	TYPE ⁽³⁾	BUFFER TYPE ⁽⁴⁾	POWER SOURCE ⁽⁵⁾	AFTER BOR (6)	
		P2.3 (RD)	I/O	LVCMOS	DVCC	OFF	
12		TA1.2	I/O	LVCMOS	DVCC	-	
	_	UCB0STE	I/O	LVCMOS	DVCC	_	
		A5	1	Analog	DVCC	_	
		P2.2 (RD)	I/O	LVCMOS	DVCC	OFF	
		TA1.1	I/O	LVCMOS	DVCC	-	
13	9	SYNC	1	LVCMOS	DVCC	_	
		A4	1	Analog	DVCC	-	
		P1.7 (RD)	I/O	LVCMOS	DVCC	OFF	
		UCA0STE	I/O	LVCMOS	DVCC	_	
14	10	TDO	0	LVCMOS	DVCC	_	
		CAP0.3	I/O	Analog	V_{REG}	_	
		P1.6 (RD)	I/O	LVCMOS	DVCC	OFF	
		UCA0CLK	I/O	LVCMOS	DVCC	_	
		TAOCLK	1	LVCMOS	DVCC	_	
15	11	TDI	1	LVCMOS	DVCC	_	
		TCLK	1	LVCMOS	DVCC	_	
		CAP0.2	I/O	Analog	V _{REG}	_	
	12	P1.5 (RD)	I/O	LVCMOS	DVCC	OFF	
		UCA0RXD	1	LVCMOS	DVCC		
		UCA0SOMI	I/O	LVCMOS	DVCC	_	
16		TA0.2	I/O	LVCMOS	DVCC	_	
		TMS	1	LVCMOS	DVCC	_	
		CAP0.1	I/O	Analog	V_{REG}	_	
		P1.4 (RD)	I/O	LVCMOS	DVCC	OFF	
	13	UCA0TXD	0	LVCMOS	DVCC		
		UCA0SIMO	I/O	LVCMOS	DVCC	_	
17		TA0.1	I/O	LVCMOS	DVCC	_	
		TCK	1	LVCMOS	DVCC	_	
		CAP0.0	I/O	Analog	V _{REG}	_	
18	14	VREG	Р	Power	V _{REG}	N/A	
		P1.3 (RD)	I/O	LVCMOS	DVCC	OFF	
		UCB0SOMI	I/O	LVCMOS	DVCC		
		UCB0SCL	I/O	LVCMOS	DVCC	_	
19	15	MCLK	0	LVCMOS	DVCC	_	
		CAP1.3 ⁽⁷⁾	I/O	Analog	V _{REG}	_	
		A3	I I	Analog	DVCC	_	
		P1.2 (RD)	I/O	LVCMOS	DVCC	OFF	
		UCB0SIMO	I/O	LVCMOS	DVCC		
		UCB0SDA	I/O	LVCMOS	DVCC	_	
20	16	SMCLK	0	LVCMOS	DVCC	_	
_0		CAP1.2 ⁽⁷⁾	I/O	Analog	V _{REG}	_	
		A2	I I	Analog	DVCC	_	
		Veref-	ı	Analog	Power	_	
		7 31 31	'	, waiog	1 GWCI		

4.3 Signal Descriptions

Table 4-2 describes the signals for all device variants and package options.

Table 4-2. Signal Descriptions

		PIN NU	JMBER	PIN		
FUNCTION	SIGNAL NAME	RHL	PW	TYPE ⁽¹⁾	DESCRIPTION	
	A0	2	2	-	Analog input A0	
	A1	1	1	I	Analog input A1	
	A2	20	16	I	Analog input A2	
	A3	19	15	Ι	Analog input A3	
ADC	A4	13	9	I	Analog input A4	
	A5	12	_	I	Analog input A5	
	A6	11	_	I	Analog input A6	
	A7	10	_	Ι	Analog input A7	
	Veref+	2	2	Ι	ADC positive reference	
	Veref-	20	16	_	ADC negative reference	
	CAP0.0	17	13	I/O	CapTIvate channel	
	CAP0.1	16	12	I/O	CapTIvate channel	
	CAP0.2	15	11	I/O	CapTIvate channel	
	CAP0.3	14	10	I/O	CapTIvate channel	
CapTlvate	CAP1.0 ⁽²⁾	2	2	I/O	CapTIvate channel	
Cupats	CAP1.1 ⁽²⁾	1	1	I/O	CapTIvate channel	
	CAP1.2 ⁽²⁾	20	16	I/O	CapTIvate channel	
	CAP1.3 ⁽²⁾	19	15	I/O	CapTlvate channel	
	SYNC	13	9	I	CapTlvate synchronous trigger input for processing and conversion	
	ACLK	1	1	I/O	ACLK output	
	MCLK	19	15	0	MCLK output	
Clock	SMCLK	20	16	0	SMCLK output	
	XIN	7	7	I	Input terminal for crystal oscillator	
	XOUT	8	8	0	Output terminal for crystal oscillator	
	SBWTCK	3	3	-	Spy-Bi-Wire input clock	
	SBWTDIO	4	4	I/O	Spy-Bi-Wire data input/output	
	TCK	17	13	l	Test clock	
Debug	TCLK	15	11	-	Test clock input	
Debug	TDI	15	11	_	Test data input	
	TDO	14	10	0	Test data output	
	TEST	3	3	I	Test mode pin – selected digital I/O on JTAG pins	
	TMS	16	12	I	Test mode select	

⁽¹⁾ Pin Types: I = Input, O = Output, I/O = Input or Output, P = Power

⁽²⁾ MSP430FR2522 only



Table 4-2. Signal Descriptions (continued)

				,			
FUNCTION	SIGNAL NAME	PIN NU	JMBER PW	PIN TYPE ⁽¹⁾	DESCRIPTION		
	P1.0	2	2	I/O	General-purpose I/O		
	P1.1	1	1	I/O	General-purpose I/O		
	P1.2	20	16	I/O	General-purpose I/O		
	P1.3	19	15	I/O	General-purpose I/O		
	P1.4	17	13	I/O	General-purpose I/O ⁽³⁾		
	P1.5	16	12	I/O	General-purpose I/O ⁽³⁾		
	P1.6	15	11	I/O	General-purpose I/O ⁽³⁾		
GPIO	P1.7	14	10	I/O	General-purpose I/O ⁽³⁾		
	P2.0	8	8	I/O	General-purpose I/O		
	P2.1	7	7	I/O	General-purpose I/O		
	P2.2	13	9	I/O	General-purpose I/O		
	P2.3	12	_	I/O	General-purpose I/O		
	P2.4	11	_	I/O	General-purpose I/O		
	P2.5	10	_	I/O	General-purpose I/O		
	P2.6	9	-	I/O	General-purpose I/O		
	UCB0SCL ⁽⁴⁾	19	15	I/O	eUSCI_B0 I ² C clock		
I ² C	UCB0SDA ⁽⁴⁾	20	16	I/O	eUSCI_B0 I ² C data		
I-C	UCB0SCL ⁽⁴⁾	9	_	I/O	eUSCI_B0 I ² C clock		
	UCB0SDA ⁽⁴⁾	10	-	I/O	eUSCI_B0 I ² C data		
	DVCC	5	5	Р	Power supply		
Power	DVSS	6	6	Р	Power ground		
rowei	VREF+	1	1	Р	Output of positive reference voltage with ground as reference		
	VREG	18	14	0	CapTIvate regulator external decoupling capacitor		
	UCA0STE	14	10	I/O	eUSCI_A0 SPI slave transmit enable		
	UCA0CLK	15	11	I/O	eUSCI_A0 SPI clock input/output		
	UCA0SOMI ⁽⁴⁾⁽⁵⁾	16	12	I/O	eUSCI_A0 SPI slave out/master in		
	UCA0SIMO ⁽⁴⁾⁽⁵⁾	17	13	I/O	eUSCI_A0 SPI slave in/master out		
	UCA0SOMI ⁽⁴⁾⁽⁵⁾	7	7	I/O	eUSCI_A0 SPI slave out/master in		
	UCA0SIMO ⁽⁴⁾⁽⁵⁾	8	8	I/O	eUSCI_A0 SPI slave in/master out		
SPI	UCB0STE ⁽⁴⁾	2	2	I/O	eUSCI_B0 slave transmit enable		
3PI	UCB0CLK ⁽⁴⁾	1	1	I/O	eUSCI_B0 clock input/output		
	UCB0SOMI ⁽⁴⁾	19	15	I/O	eUSCI_B0 SPI slave out/master in		
	UCB0SIMO ⁽⁴⁾	20	16	I/O	eUSCI_B0 SPI slave in/master out		
	UCB0STE (4)	12	_	I/O	eUSCI_B0 slave transmit enable		
	UCB0CLK ⁽⁴⁾	11	_	I/O	eUSCI_B0 clock input/output		
	UCB0SOMI ⁽⁴⁾	9		I/O	eUSCI_B0 SPI slave out/master in		
	UCB0SIMO ⁽⁴⁾	10	-	I/O	eUSCI_B0 SPI slave in/master out		
System	NMI	4	4	ı	Nonmaskable interrupt input		
Cystelli	RST	4	4	I	Active-low reset input		

⁽³⁾ Because this pin is multiplexed with the JTAG function, TI recommends disabling the pin interrupt function while in JTAG debug to

prevent collisions.

These signal assignments are controlled by the USCIARMP bit of the SYSCFG3 register or the USCIBRMP bit of the SYSCFG2 register. Only one group can be selected at one time.

Signal assignments on these pins are controlled by the remap functionality and are selected by the USCIARMP bit in the SYSCFG3 register. Only one group can be selected at one time. The CLK and STE assignments are fixed and shared by both SPI function groups.

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Table 4-2. Signal Descriptions (continued)

FUNCTION	SIGNAL NAME	PIN NUMBER		PIN	DESCRIPTION
FUNCTION	SIGNAL NAME	RHL	PW	TYPE ⁽¹⁾	DESCRIPTION
	TA0.1	17	13	I/O	Timer TA0 CCR1 capture: CCI1A input, compare: Out1 outputs
	TA0.2	16	12	I/O	Timer TA0 CCR2 capture: CCI2A input, compare: Out2 outputs
	TA0CLK	15	11	I	Timer clock input TACLK for TA0
Timer_A	TA1.1	13	9	I/O	Timer TA1 CCR1 capture: CCI1A input, compare: Out1 outputs
	TA1.2	12	_	I/O	Timer TA1 CCR2 capture: CCl2A input, compare: Out2 outputs
	TA1CLK	11	_	I	Timer clock input TACLK for TA1
	UCA0RXD ⁽⁴⁾	16	12	ı	eUSCI_A0 UART receive data
	UCA0TXD ⁽⁴⁾	17	13	0	eUSCI_A0 UART transmit data
UART	UCA0RXD ⁽⁴⁾	7	7	ı	eUSCI_A0 UART receive data
	UCA0TXD ⁽⁴⁾	8	8	0	eUSCI_A0 UART transmit data
QFN Pad	QFN thermal pad	Pad	-	_	QFN package exposed thermal pad. TI recommends connecting to V_{SS} .



4.4 Pin Multiplexing

Pin multiplexing for this MCU is controlled by both register settings and operating modes (for example, if the MCU is in test mode). For details of the settings for each pin and diagrams of the multiplexed ports, see Section 6.11.

4.5 Buffer Types

Table 4-3 defines the pin buffer types that are listed in Table 4-1

Table 4-3. Buffer Types

BUFFER TYPE (STANDARD)	NOMINAL VOLTAGE	HYSTERESIS	PU OR PD	NOMINAL PU OR PD STRENGTH (μA)	OUTPUT DRIVE STRENGTH (mA)	OTHER CHARACTERISTICS
LVCMOS	3.0 V	Y ⁽¹⁾	Programmable	See Section 5.11.4	See Section 5.11.4	
Analog	3.0 V	N	N/A	N/A	N/A	See analog modules in Section 5 for details.
Power (DVCC)	3.0 V	N	N/A	N/A	N/A	SVS enables hysteresis on DVCC.
Power (AVCC)	3.0 V	N	N/A	N/A	N/A	

⁽¹⁾ Only for input pins.

4.6 Connection of Unused Pins

Table 4-4 lists the correct termination of unused pins.

Table 4-4. Connection of Unused Pins⁽¹⁾

PIN	POTENTIAL	COMMENT
Px.0 to Px.7	Open	Switched to port function, output direction (PxDIR.n = 1)
RST/NMI	DV _{CC}	47-kΩ pullup or internal pullup selected with 10-nF (or 1.1-nF) pulldown ⁽²⁾
TEST	Open	This pin always has an internal pull-down enabled.

⁽¹⁾ Any unused pin with a secondary function that is shared with general-purpose I/O should follow the Px.0 to Px.7 unused pin connection guidelines.

⁽²⁾ The pulldown capacitor should not exceed 1.1 nF when using MCUs with Spy-Bi-Wire interface in Spy-Bi-Wire mode with TI tools like FET interfaces or GANG programmers.



5 Specifications

5.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Voltage applied at DVCC pin to V _{SS}	-0.3	4.1	V
Voltage applied to any pin in CapTlvate mode (2)	-0.3	V_{REG}	V
Voltage applied to any other pin ⁽³⁾	-0.3 (4.	V _{CC} + 0.3 1 V Max)	V
Diode current at any device pin		±2	mA
Maximum junction temperature, T _J		85	°C
Storage temperature, T _{stg} ⁽⁴⁾	-40	125	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±1000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±250	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±1000 V may actually have higher performance.

5.3 Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage applied at DVCC pin ⁽¹⁾⁽²⁾⁽³⁾		1.8		3.6	٧
V_{SS}	Supply voltage applied at DVSS pin			0		٧
T _A	Operating free-air temperature		-40		85	°C
T _J	Operating junction temperature		-40		85	°C
C _{DVCC}	Recommended capacitor at DVCC ⁽⁴⁾		4.7	10		μF
_	Down (as a first MOLK (No FRAM wait states (NWAITSx = 0)	0		8	N.41.1-
f _{SYSTEM}	Processor frequency (maximum MCLK frequency) (3) (5)	With FRAM wait states (NWAITSx = 1) ⁽⁶⁾	0		0 85 85	MHz
f _{ACLK}	Maximum ACLK frequency	·			40	kHz
f _{SMCLK}	Maximum SMCLK frequency				16 ⁽⁷⁾	MHz

⁽¹⁾ Supply voltage changes faster than 0.2 V/µs can trigger a BOR reset even within the recommended supply voltage range.

⁽²⁾ This applies I/Os worked in CapTIvate mode.

⁽³⁾ All voltages referenced to V_{SS}.

⁽⁴⁾ Higher temperature may be applied during board soldering according to the current JEDEC J-STD-020 specification with peak reflow temperatures not higher than classified on the device label on the shipping boxes or reels.

⁽²⁾ JEDEC document JÉP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±250 V may actually have higher performance.

²⁾ Modules may have a different supply voltage range specification. See the specification of the respective module in this data sheet.

The minimum supply voltage is defined by the SVS levels. See the SVS threshold parameters in Table 5-2.

 ⁽⁴⁾ A capacitor tolerance of ±20% or better is required.
 (5) Modules may have a different maximum input clock specification. See the specification of the respective module in this data sheet.

⁽⁶⁾ Wait states only occur on actual FRAM accesses (that is, on FRAM cache misses). RAM and peripheral accesses are always executed without wait states.

⁽⁷⁾ If clock sources such as HF crystals or the DCO with frequencies >16 MHz are used, the clock must be divided in the clock system to comply with this operating condition.



Active Mode Supply Current Into V_{CC} Excluding External Current

See (1)

			FREQUENCY (f _{MCLK} = f _{SMCLK})						
PARAMETER	EXECUTION MEMORY	TEST CONDITION	1 MHz 0 WAIT STATES (NWAITSx = 0)		8 MHz 0 WAIT STATES (NWAITSx = 0)		16 MHz 1 WAIT STATE (NWAITSx = 1)		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	
1 (00/)	FRAM	3 V, 25°C	454		2620		2935		
I _{AM, FRAM} (0%)	0% cache hit ratio	3 V, 85°C	471		2700		2980	3250	μA
	FRAM	3 V, 25°C	191		573		950		
I _{AM, FRAM} (100%)	100% cache hit ratio	3 V, 85°C	199		592		974	1200	μA
I _{AM, RAM} ⁽²⁾	RAM	3 V, 25°C	216		772		1300		μΑ

⁽¹⁾ All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current. Characterized with program executing typical data

5.5 Active Mode Supply Current Per MHz

 $V_{CC} = 3 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}$

		PARAMETER	TEST CONDITIONS	TYP	UNIT
dl _{AM,}	,FRAM/df		[I _{AM} (75% cache hit rate) at 8 MHz – I _{AM} (75% cache hit rate) at 1 MHz) / 7 MHz	120	μΑ/MHz

5.6 Low-Power Mode (LPM0) Supply Currents Into V_{CC} Excluding External Current

 $V_{CC} = 3 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}^{(1)(2)}$

	V _{CC}	FREQUENCY (f _{SMCLK})						
PARAMETER		1 MHz		8 MHz		16 MHz		UNIT
		TYP	MAX	TYP	MAX	TYP	MAX	
	2 V	145		292		395		
ILPM0	3 V	155		300		394		μA

⁽¹⁾ All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current.

 $f_{ACLK} = 32768$ Hz, $f_{MCLK} = f_{SMCLK} = f_{DCO}$ at specified frequency Program and data entirely reside in FRAM. All execution is from FRAM.

⁽²⁾ Program and data reside entirely in RAM. All execution is from RAM. No access to FRAM.

Current for watchdog timer clocked by SMCLK included.

 $f_{ACLK} = 32768 \text{ Hz}$, $f_{MCLK} = 0 \text{ MHz}$, f_{SMCLK} at specified frequency.



5.7 Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{cc}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1)

	DADAMETED	.,	-40	°C	25°	С	85°	С	LINUT
	PARAMETER	V _{CC}	TYP	MAX	TYP	MAX	TYP	MAX	UNIT
1	Low-power mode 3, 12.5-pF crystal, includes	3 V	0.96		1.11		2.75	6.2	
I _{LPM3,XT1}	SVS ⁽²⁾⁽³⁾⁽⁴⁾	2 V	0.93		1.08		2.78		μA
1	Low-power mode 3, VLO, excludes SVS ⁽⁵⁾	3 V	0.77		0.92		2.66	6.0	
I _{LPM3,VLO}	Low-power mode 3, VLO, excludes 3V3	2 V	0.75		0.90		2.60		μA
I _{LPM3, RTC}	Low-power mode 3, RTC, excludes SVS ⁽⁶⁾	3 V	0.90		1.05		2.77		μΑ
I _{LPM3} , CapTIvate, 1 proximity, wake on touch	Low-power mode 3, CapTlvate , excludes SVS ⁽⁷⁾	3 V			4.7				μΑ
I _{LPM3} , CapTIvate, 1 button, wake on touch	Low-power mode 3, CapTlvate , excludes SVS ⁽⁸⁾	3 V			3.0				μΑ
I _{LPM3} , CapTIvate, 2 buttons, wake on touch	Low-power mode 3, CapTlvate, excludes SVS ⁽⁹⁾	3 V			3.2				μΑ
I _{LPM3} , CapTIvate, 8 buttons	Low-power mode 3, CapTlvate, excludes SVS ⁽¹⁰⁾	3 V			17				μΑ
I _{LPM3} , CapTIvate, 16 buttons	Low-power mode 3, CapTlvate, excludes SVS ⁽¹¹⁾	3 V			38				μΑ
h	Low-power mode 4, includes SVS ⁽¹²⁾	3 V	0.51		0.64		2.30		μA
I _{LPM4} , SVS	Low-power mode 4, includes SVS(12)	2 V	0.49		0.61		2.25		μΛ
1	Low-power mode 4, excludes SVS ⁽¹²⁾	3 V	0.35		0.48		2.13		
I _{LPM4}	Low-power mode 4, excludes 575	2 V	0.34		0.46		2.10		μA

- (1) All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current.
- (2) Not applicable for MCUs with HF crystal oscillator only.
- (3) Characterized with a Seiko Crystal SC-32S crystal with a load capacitance chosen to closely match the required load.
- (4) Low-power mode 3, 12.5-pF crystal, includes SVS test conditions:
 - Current for watchdog timer clocked by ACLK and RTC clocked by XT1 included. Current for brownout and SVS included (SVSHE = 1). CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 0 (LPM3),
 - $f_{XT1} = 32768 \text{ Hz}, f_{ACLK} = f_{XT1}, f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}$
- (5) Low-power mode 3, VLO, excludes SVS test conditions:
 - Current for watchdog timer clocked by VLO included. RTC disabled. Current for brownout included. SVS disabled (SVSHE = 0). CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 0 (LPM3)
 - $f_{XT1} = 32768 \text{ Hz}, f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}$
- (6) RTC periodically wakes up every second with external 32768-Hz input as source.
- (7) CapTlvate technology works in LPM3 with one proximity sensor for wake on touch. CapTlvate BSWP demonstration board with 1.5-mm overlay. Current for brownout included. SVS disabled (SVSHE = 0).
 f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 800
- (8) CapTIvate technology works in LPM3 with one button, wake on touch.CapTIvate BSWP demonstration board with 1.5-mm overlay, Current for brownout included. SVS disabled (SVSHE = 0). f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 250
- (9) CapTIvate technology works in LPM3 with two self-capacitance buttons, wake on touch. CapTIvate BSWP demonstration board with 1.5-mm overlay. Current for brownout included. SVS disabled (SVSHE = 0). f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 250
- (10) CapTIvate technology works in LPM3 with 8 self-capacitance buttons. The CPU enters active mode in between time cycles to configure the conversions and read the results. CapTIvate BSWP demonstration board with 1.5-mm overlay. Current for brownout included. SVS disabled (SVSHE = 0).

configure the conversions and read the results. CapTlvate phone demonstration board with 1.5-mm overlay. Current for brownout

- f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 250

 (11) CapTIvate technology works in LPM3 with 16 mutual-capacitance buttons. The CPU enters active mode in between time cycles to
 - included. SVS disabled (SVSHE = 0). $f_{SCAN} = 8$ Hz, $f_{CONVER} = 2$ MHz, COUNTS = 250
- (12) Low-power mode 4, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPM4), CPU and all clocks are disabled, WDT and RTC disabled



Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{CC}) Excluding External Current *(continued)*

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1)

	DADAMETED	v	-40°	°C	25°	С	85°	С	LINUT
	PARAMETER	V _{CC}	TYP	MAX	TYP	MAX	TYP	MAX	UNIT
	Low-power mode 4, RTC is soured from VLO,	3 V	0.43		0.56		2.21		
I _{LPM4,VLO}	excludes SVS ⁽¹³⁾	2 V	0.42		0.55		2.19		μA
	Low-power mode 4, RTC is soured from XT1,	3 V	0.80		0.96		2.68		
I _{LPM4,XT1}	excludes SVS ⁽¹⁴⁾	2 V	0.79		0.94		2.64		μΑ
I _{LPM4} , CapTIvate, 1 proximity, wake on touch	Low-power mode 4, CapTIvate , excludes SVS ⁽¹⁵⁾	3 V			4.5				μA
I _{LPM4} , CapTlvate, 1 button, wake on touch	Low-power mode 4, CapTlvate , excludes SVS ⁽¹⁶⁾	3 V			2.7				μΑ
ILPM4, CapTlvate, 2 buttons, wake on touch	Low-power mode 4, CapTlvate, excludes SVS ⁽¹⁷⁾	3 V			2.9				μΑ
I _{LPM4} , CapTIvate, 8 buttons	Low-power mode 4, CapTlvate, excludes SVS ⁽¹⁸⁾	3 V			18				μΑ
I _{LPM4} , CapTIvate, 16 buttons	Low-power mode 4, CapTlvate, excludes SVS ⁽¹⁹⁾	3 V			39				μΑ

(13) Low-power mode 4, VLO, excludes SVS test conditions:

Current for RTC clocked by VLO included. Current for brownout included. SVS disabled (SVSHE = 0).

CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPM4)

 $f_{XT1} = 0 \text{ Hz}, f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}$

(14) Low-power mode 4, XT1, excludes SVS test conditions:

Current for RTC clocked by XT1 included. Current for brownout included. SVS disabled (SVSHE = 0).

CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPM4)

 $f_{XT1} = 32768 \text{ Hz}, f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}$

- (15) CapTIvate technology works in LPM4 with one proximity sensor for wake on touch. CapTIvate BSWP demonstration board with 1.5-mm overlay. Current for brownout included. SVS disabled (SVSHE = 0). The VLO (10 kHz) sources the CapTIvate timer, no external crystal. f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 800
- (16) CapTIvate technology works in LPM4 with one button, wake on touch. CapTIvate BSWP demonstration board with 1.5-mm overlay, Current for brownout included. SVS disabled (SVSHE = 0). The VLO (10 kHz) sources the CapTIvate timer, no external crystal. f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 250
- (17) CapTIvate technology works in LPM4 with two self-capacitance buttons, wake on touch. CapTIvate BSWP demonstration board with 1.5-mm overlay. Current for brownout included. SVS disabled (SVSHE = 0). VLO (10 kHz) sources the CapTIvate timer, no external crystal.
 - f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 250
- (18) CapTIvate technology works in LPM4 with 8 self-capacitance buttons. The CPU enters active mode in between time cycles to configure the conversions and read the results. CapTIvate BSWP demonstration board with 1.5-mm overlay. Current for brownout included. SVS disabled (SVSHE = 0). The VLO (10 kHz) sources the CapTIvate timer, no external crystal.

 f_SCAN = 8 Hz, f_CONVER = 2 MHz, COUNTS = 250
- (19) CapTIvate technology works in LPM4 with 16 mutual-capacitance buttons. The CPU enters active mode in between time cycles to configure the conversions and read the results. CapTIvate phone demonstration board with 1.5-mm overlay. Current for brownout included. SVS disabled (SVSHE = 0). The VLO (10 kHz) sources the CapTIvate timer, no external crystal. f_{SCAN} = 8 Hz, f_{CONVER} = 2 MHz, COUNTS = 250



5.8 Low-Power Mode (LPMx.5) Supply Currents (Into V_{CC}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	DADAMETED	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-40°C		25°C		85°C		UNIT
	PARAMETER	V _{CC}	TYP	MAX	TYP	MAX	TYP	MAX	UNII
	Low-power mode 3.5, 12.5-pF crystal, includes	3 V	0.57		0.63		0.81	1.54	
I _{LPM3.5, XT1}	SVS ^{(1)(2) (3)} (also see Figure 5-3)	2 V	0.54		0.60		0.79		μA
	1 15 : 1 1 0 (4)	3 V	0.23		0.25		0.31	0.45	
ILPM4.5, SVS	Low-power mode 4.5, includes SVS ⁽⁴⁾	2 V	0.21		0.23		0.29		μA
	Low-power mode 4.5, excludes SVS ⁽⁵⁾	3 V	0.027		0.036		0.080	0.15	
ILPM4.5		2 V	0.022		0.031		0.073		μA

- (1) Not applicable for MCUs with HF crystal oscillator only.
- (2) Characterized with a Seiko Crystal SC-32S crystal with a load capacitance chosen to closely match the required load.
- (3) Low-power mode 3.5, 12.5-pF crystal, includes SVS test conditions:

 Current for RTC clocked by XT1 included. Current for brownout and SVS included (SVSHE = 1). Core regulator disabled.

 PMMREGOFF = 1, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPMx.5),
- f_{XT1} = 32768 Hz, f_{ACLK} = 0, f_{MCLK} = f_{SMCLK} = 0 MHz

 (4) Low-power mode 4.5, includes SVS test conditions:

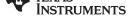
 Current for brownout and SVS included (SVSHE = 1). Core regulator disabled.

 PMMREGOFF = 1, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPMx.5) f_{XT1} = 0 Hz, f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0 MHz
- (5) Low-power mode 4.5, excludes SVS test conditions:

 Current for brownout included. SVS disabled (SVSHE = 0). Core regulator disabled.

 PMMREGOFF = 1, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPMx.5)

 f_{XT1} = 0 Hz, f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0 MHz



5.9 Typical Characteristics - Low-Power Mode Supply Currents

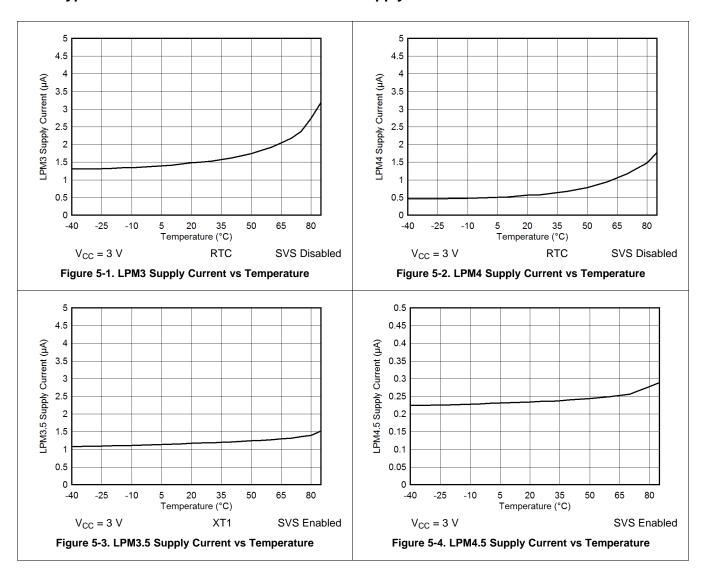


Table 5-1. Typical Characteristics - Current Consumption Per Module

MODULE	TEST CONDITIONS	REFERENCE CLOCK	MIN TYP	MAX	UNIT
Timer_A		Module input clock	5		μΑ/MHz
eUSCI_A	UART mode	Module input clock	7		μΑ/MHz
eUSCI_A	SPI mode	Module input clock	5		μΑ/MHz
eUSCI_B	SPI mode	Module input clock	5		μΑ/MHz
eUSCI_B	I ² C mode, 100 kbaud	Module input clock	5		μΑ/MHz
RTC		32 kHz	85		nA
CRC	From start to end of operation	MCLK	8.5		µA/MHz



5.10 Thermal Resistance Characteristics

	THERMAL METRIC ⁽¹⁾		VALUE ⁽²⁾	UNIT
Do	$R\theta_{JA}$ Junction-to-ambient thermal resistance, still air	VQFN 20 pin (RHL)	37.8	°C/W
Көјд	Junction-to-ambient thermal resistance, still all	TSSOP 16 pin (PW16)	101.7	°C/VV
Do	Rθ _{JC} Junction-to-case (top) thermal resistance	VQFN 20 pin (RHL)	34.1	°C/W
KAIC		TSSOP 16 pin (PW16)	33.7	°C/VV
Do	live stice to be and the armal registers of	VQFN 20 pin (RHL)	15.3	°C/W
$R\theta_{JB}$	Junction-to-board thermal resistance	TSSOP 16 pin (PW16)	47.5	°C/VV

- (1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.
- (2) These values are based on a JEDEC-defined 2S2P system (with the exception of the Theta JC (Rθ_{JC}) value, which is based on a JEDEC-defined 1S0P system) and will change based on environment and application. For more information, see these EIA/JEDEC standards:
 - JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions Natural Convection (Still Air)
 - JESD51-3, Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages
 - JESD51-7, High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages
 - JESD51-9, Test Boards for Area Array Surface Mount Package Thermal Measurements

5.11 Timing and Switching Characteristics

5.11.1 Power Supply Sequencing

Table 5-2 lists the characteristics of the SVS and BOR.

Table 5-2. PMM, SVS and BOR

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{BOR, safe}	Safe BOR power-down level ⁽¹⁾		0.1			V
t _{BOR, safe}	Safe BOR reset delay ⁽²⁾		10			ms
I _{SVSH,AM}	SVS _H current consumption, active mode	V _{CC} = 3.6 V			1.5	μΑ
I _{SVSH,LPM}	SVS _H current consumption, low-power modes	V _{CC} = 3.6 V		240		nA
V _{SVSH} -	SVS _H power-down level ⁽³⁾		1.71	1.80	1.87	V
V _{SVSH+}	SVS _H power-up level ⁽³⁾		1.76	1.88	1.99	V
V _{SVSH_hys}	SVS _H hysteresis			80		mV
t _{PD,SVSH,}	SVS _H propagation delay, active mode				10	μs
t _{PD,SVSH,} LPM	SVS _H propagation delay, low-power modes				100	μs

- 1) A safe BOR can be correctly generated only if DVCC drops below this voltage before it rises.
- (2) When an BOR occurs, a safe BOR can be correctly generated only if DVCC is kept low longer than this period before it reaches V_{SVSH+}.
- (3) For additional information, see the Dynamic Voltage Scaling Power Solution for MSP430 Devices With Single-Channel LDO Reference Design.

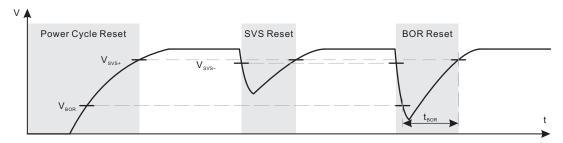


Figure 5-5. Power Cycle, SVS, and BOR Reset Conditions



5.11.2 Reset Timing

Table 5-3 lists the timing characteristics of wakeup from LPMs and reset.

Table 5-3. Wake-up Times From Low-Power Modes and Reset

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP	MAX	UNIT
t _{WAKE-UP} FRAM	Additional wake-up time to activate the FRAM in AM if previously disabled by the FRAM controller or from a LPM if immediate activation is selected for wakeup ⁽¹⁾		3 V	10		рs
twake-up LPM0	Wake-up time from LPM0 to active mode ⁽¹⁾		3 V		200 + 2.5 / f _{DCO}	ns
t _{WAKE-UP LPM3}	Wake-up time from LPM3 to active mode (2)		3 V	10		μs
t _{WAKE-UP LPM4}	Wake-up time from LPM4 to active mode		3 V	10		μs
t _{WAKE-UP LPM3.5}	Wake-up time from LPM3.5 to active mode (2)		3 V	350		μs
	Wake-up time from LPM4.5 to active mode (2)	SVSHE = 1	3 V	350		μs
twake-up lpm4.5	wake-up time from LPM4.5 to active mode V	SVSHE = 0	3 V	1	200 +	ms
t _{WAKE-UP-RESET}	Wake-up time from $\overline{\rm RST}$ or BOR event to active mode $^{(2)}$		3 V	1		ms
t _{RESET}	Pulse duration required at RST/NMI pin to accept a reset		3 V	2		μs

⁽¹⁾ The wake-up time is measured from the edge of an external wake-up signal (for example, port interrupt or wake-up event) to the first externally observable MCLK clock edge.

⁽²⁾ The wake-up time is measured from the edge of an external wake-up signal (for example, port interrupt or wake-up event) until the first instruction of the user program is executed.



5.11.3 Clock Specifications

Table 5-4 lists the characteristics of the LF XT1.

Table 5-4. XT1 Crystal Oscillator (Low Frequency)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{XT1, LF}	XT1 oscillator crystal, low frequency	LFXTBYPASS = 0			32768		Hz
DC _{XT1, LF}	XT1 oscillator LF duty cycle	Measured at MCLK, f _{LFXT} = 32768 Hz		30%		70%	
f _{XT1,SW}	XT1 oscillator logic-level square- wave input frequency	LFXTBYPASS = 1 (2)(3)			32.768		kHz
DC _{XT1, SW}	LFXT oscillator logic-level square- wave input duty cycle	LFXTBYPASS = 1		40%		60%	
OA _{LFXT}	Oscillation allowance for LF crystals ⁽⁴⁾	LFXTBYPASS = 0, LFXTDRIVE = $\{3\}$, $f_{LFXT} = 32768 \text{ Hz}$, $C_{L,eff} = 12.5 \text{ pF}$			200		kΩ
C _{L,eff}	Integrated effective load capacitance ⁽⁵⁾	See (6)			1		pF
t _{START,LFXT}	Start-up time ⁽⁷⁾	$\begin{split} f_{OSC} &= 32768 \text{ Hz}, \\ \text{LFXTBYPASS} &= 0, \text{LFXTDRIVE} = \{3\}, \\ T_{A} &= 25^{\circ}\text{C}, \text{ C}_{\text{L,eff}} = 12.5 \text{ pF} \end{split}$			1000		ms
f _{Fault,LFXT}	Oscillator fault frequency (8)	$XTS = 0^{(9)}$	·	0		3500	Hz

- To improve EMI on the LFXT oscillator, observe the following guidelines:
 - Keep the trace between the device and the crystal as short as possible.
 - Design a good ground plane around the oscillator pins.
 - Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.
 - Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
 - Use assembly materials and processes that avoid any parasitic load on the oscillator XIN and XOUT pins.
 - If conformal coating is used, make sure that it does not induce capacitive or resistive leakage between the oscillator pins. When LFXTBYPASS is set, LFXT circuits are automatically powered down. Input signal is a digital square wave with parametrics defined in the Schmitt-trigger inputs section of this data sheet. Duty cycle requirements are defined by DC_{LFXT. SW}.
- Maximum frequency of operation of the entire device cannot be exceeded.
- Oscillation allowance is based on a safety factor of 5 for recommended crystals. The oscillation allowance is a function of the LFXTDRIVE settings and the effective load. In general, comparable oscillator allowance can be achieved based on the following guidelines, but should be evaluated based on the actual crystal selected for the application:
 - For LFXTDRIVE = $\{0\}$, $C_{L,eff} = 3.7 pF$
 - For LFXTDRIVE = {1}, 6 pF \leq C_{L,eff} \leq 9 pF
 - For LFXTDRIVE = {2}, 6 pF \leq C_{L,eff} \leq 10 pF For LFXTDRIVE = {3}, 6 pF \leq C_{L,eff} \leq 12 pF
- Includes parasitic bond and package capacitance (approximately 2 pF per pin).
- Requires external capacitors at both terminals. Values are specified by crystal manufacturers.
- Includes start-up counter of 1024 clock cycles.
- Frequencies above the MAX specification do not set the fault flag. Frequencies between the MIN and MAX specifications might set the flag. A static condition or stuck at fault condition sets the flag.
- Measured with logic-level input frequency but also applies to operation with crystals.

Table 5-5 lists the frequency characteristics of the FLL.

Table 5-5. DCO FLL, Frequency

over recommended operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
	FLL lock frequency, 16 MHz, 25°C	Measured at MCLK, Internal	3 V	-1.0%		1.0%	
f _{DCO, FLL}	FLL lock frequency, 16 MHz, -40°C to 85°C	trimmed REFO as reference	3 V	-2.0%		2.0%	
	FLL lock frequency, 16 MHz, -40°C to 85°C	Measured at MCLK, XT1 crystal as reference	3 V	-0.5%		0.5%	
f_{DUTY}	Duty cycle		3 V	40%	50%	60%	
Jitter _{cc}	Cycle-to-cycle jitter, 16 MHz	Measured at MCLK, XT1	3 V		0.25%		
Jitter _{long}	Long term jitter, 16 MHz	crystal as reference	3 V		0.022%		
t _{FLL, lock}	FLL lock time, 16MHz		3 V		280		ms

Specifications



Table 5-6 lists the characteristics of the DCO.

Table 5-6. DCO Frequency

over recommended operating free-air temperature (unless otherwise noted) (see Figure 5-6)

	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
		DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0		7.1	
face	DCO frequency, 16 MHz	DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511	3 V	11.8	MHz
f _{DCO} , 16MHz	DCO frequency, 10 Miliz	DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0		17	IVII IZ
		DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		27.7	
		DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0		5.5	
f	DCO frequency, 12 MHz	DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511	3 V	9.1	MHz
[†] DCO, 12MHz	DOO frequency, 12 Miliz	DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0	3 V	13.1	MHZ
		DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		21.5	
		DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0		3.7	
f _{DCO, 8MHz}	DCO frequency, 8 MHz	DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511	2.1/	6.3	NALI
	200 110400110,, 0 111112	DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0	3 V	9.0	MHz
		DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		14.9	
		DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0		1.9	MHz
4	DCO fraguency 4 MHz	DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511	3 V	3.2	
[†] DCO, 4MHz	DCO frequency, 4 MHz	DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0	3 V	4.6	
		DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		7.8	
		DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0		0.96	
f	DCO froquency 2 MH=	DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511	21/	1.6	MU>
[†] DCO, 2MHz	DCO frequency, 2 MHz	DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0	3 V	2.3	MHz
		DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		4.0	
		DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0		0.5	
£	DCO fraguence: 4 MHz	DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511	2.1/	0.85	N.41.1-
f _{DCO} , 1MHz	DCO frequency, 1 MHz	DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0	3 V	1.2	MHz
		DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		2.0	

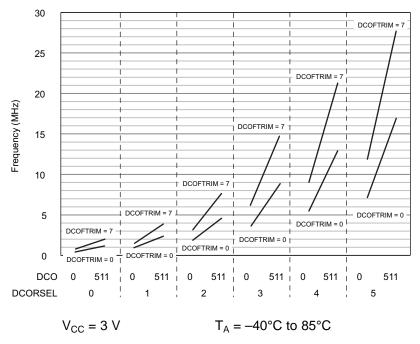


Figure 5-6. Typical DCO Frequency

Table 5-7 lists the characteristics of the REFO.

Table 5-7. REFO

over recommended operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
I _{REFO}	REFO oscillator current consumption	T _A = 25°C	3 V		15		μΑ
	REFO calibrated frequency	Measured at MCLK	3 V		32768		Hz
f _{REFO}	REFO absolute calibrated tolerance	-40°C to 85°C	1.8 V to 3.6 V	-3.5%		+3.5%	
df _{REFO} /d _T	REFO frequency temperature drift	Measured at MCLK ⁽¹⁾	3 V		0.01		%/°C
$\begin{array}{c} df_{REFO}/\\ d_{VCC} \end{array}$	REFO frequency supply voltage drift	Measured at MCLK at 25°C (2)	1.8 V to 3.6 V		1		%/V
f_{DC}	REFO duty cycle	Measured at MCLK	1.8 V to 3.6 V	40%	50%	60%	
t _{START}	REFO start-up time	40% to 60% duty cycle			50		μs

- (1) Calculated using the box method: (MAX(-40°C to 85°C) MIN(-40°C to 85°C)) / MIN(-40°C to 85°C) / (85°C (-40°C))
- (2) Calculated using the box method: (MAX(1.8 V to 3.6 V) MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V 1.8 V)

RUMENTS

Table 5-8 lists the characteristics of the VLO.

Table 5-8. Internal Very-Low-Power Low-Frequency Oscillator (VLO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
f_{VLO}	VLO frequency	Measured at MCLK	3 V	10	kHz
df_{VLO}/d_{T}	VLO frequency temperature drift	Measured at MCLK ⁽¹⁾	3 V	0.5	%/°C
df_{VLO}/dV_{CC}	VLO frequency supply voltage drift	Measured at MCLK ⁽²⁾	1.8 V to 3.6 V	4	%/V
$f_{VLO,DC}$	Duty cycle	Measured at MCLK	3 V	50%	

- Calculated using the box method: (MAX(-40°C to 85°C) MIN(-40°C to 85°C)) / MIN(-40°C to 85°C) / (85°C (-40°C))
- Calculated using the box method: (MAX(1.8 V to 3.6 V) MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V 1.8 V)

NOTE

The VLO clock frequency is reduced by 15% (typical) when the device switches from active mode to LPM3 or LPM4, because the reference changes. This lower frequency is not a violation of the VLO specifications (see Table 5-8).

Table 5-9 lists the characteristics of the MODOSC.

Table 5-9. Module Oscillator (MODOSC)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
f _{MODOSC}	MODOSC frequency		3 V	3.8	4.8	5.8	MHz
f _{MODOSC} /dT	MODOSC frequency temperature drift		3 V		0.102		%/°C
f_{MODOSC}/dV_{CC}	MODOSC frequency supply voltage drift		1.8 V to 3.6 V		1.02		%/V
f _{MODOSC,DC}	Duty cycle		3 V	40%	50%	60%	

STRUMENTS

5.11.4 Digital I/Os

Table 5-10 lists the characteristics of the digital inputs.

Table 5-10. Digital Inputs

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V	Desitive gains input threshold valtege		2 V	0.90		1.50	V
V _{IT+}	Positive-going input threshold voltage		3 V	1.35		2.25	V
V	Negative going input threshold voltage		2 V	0.50		1.10	V
V _{IT}	Negative-going input threshold voltage		3 V	0.75		1.65	V
V			2 V	0.3		0.8	V
V _{hys}			3 V	0.4		1.2	V
R _{Pull}	Pullup or pulldown resistor	For pullup: V _{IN} = V _{SS} For pulldown: V _{IN} = V _{CC}		20	35	50	kΩ
$C_{I,dig}$	Input capacitance, digital only port pins	$V_{IN} = V_{SS}$ or V_{CC}			3		pF
C _{I,ana}	Input capacitance, port pins with shared analog functions	$V_{IN} = V_{SS}$ or V_{CC}			5		pF
I _{lkg(Px.y)}	High-impedance leakage current of GPIO pins	See (1) (2)	2 V, 3 V	-20		20	nA
I _{lkg(Px.y)}	High-impedance leakage current of GPIO pins shared with CapTIvate functionality	See (1) (2)(3)	2 V, 3 V	-30		30	nA
t _(int)	External interrupt timing (external trigger pulse duration to set interrupt flag) (4)	Ports with interrupt capability (see block diagram and terminal function descriptions)	2 V, 3 V	50			ns

- The leakage current is measured with VSS or VCC applied to the corresponding pins, unless otherwise noted.
- The leakage of the digital port pins is measured individually. The port pin is selected for input and the pullup or pulldown resistor is disabled.
- Applies only to GPIOs that are shared with CapTIvate I/Os
- An external signal sets the interrupt flag every time the minimum interrupt pulse duration $t_{(int)}$ is met. It may be set by trigger signals shorter than t(int).

Table 5-11 lists the characteristics of the digital outputs.

Table 5-11. Digital Outputs

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT	
V	High level output voltage	$I_{(OHmax)} = -3 \text{ mA}^{(1)}$	2 V	1.4		2.0	V	
V _{OH}	High-level output voltage	$I_{(OHmax)} = -5 \text{ mA}^{(1)}$	3 V	2.4		3.0	V	
\/	Low-level output voltage	$I_{(OLmax)} = 3 \text{ mA}^{(1)}$	2 V	0.0		0.60	V	
V _{OL}	Low-level output voltage	$I_{(OHmax)} = 5 \text{ mA}^{(1)}$	3 V	0.0		0.60	V	
4	Clock output frequency	C _L = 20 pF ⁽²⁾	2 V	16			MHz	
f _{Port_CLK}	Clock output frequency	$G_L = 20 \text{ pr}^{*}$	3 V	16			IVITZ	
	Dort output vice time digital only part pine	C 20 %F	2 V		10		20	
t _{rise,dig}	Port output rise time, digital only port pins	$C_L = 20 \text{ pF}$	3 V		7		ns	
	Dort output fall time digital only part pine	C 20 x F	2 V		10			
t _{fall,dig}	Port output fall time, digital only port pins	C _L = 20 pF	3 V		5		ns	

The maximum total current, I_(OHmax) and I_(OLmax), for all outputs combined should not exceed ±48 mA to hold the maximum voltage drop specified.

The port can output frequencies at least up to the specified limit and might support higher frequencies.



5.11.4.1 Typical Characteristics – Outputs at 3 V and 2 V

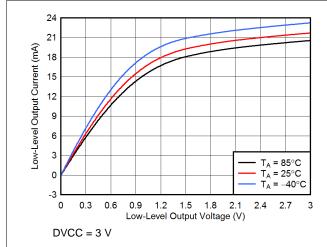


Figure 5-7. Typical Low-Level Output Current vs Low-Level Output Voltage

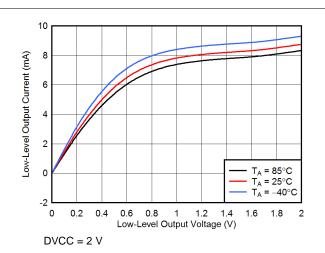


Figure 5-8. Typical Low-Level Output Current vs Low-Level Output Voltage

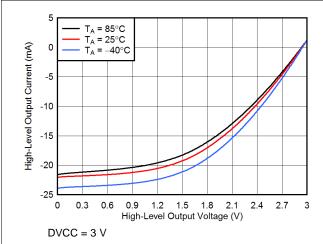


Figure 5-9. Typical High-Level Output Current vs High-Level Output Voltage

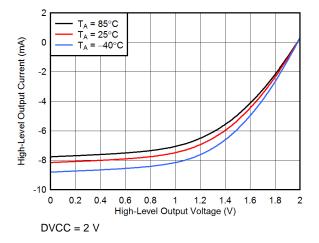


Figure 5-10. Typical High-Level Output Current vs High-Level Output Voltage



5.11.5 VREF+ Built-in Reference

Table 5-12 lists the characteristics of the VREF+.

Table 5-12. VREF+

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
V_{REF+}	Positive built-in reference voltage	EXTREFEN = 1 with 1-mA load current	2 V, 3 V	1.15	1.19	1.23	V
TC _{REF+}	Temperature coefficient of built-in reference voltage				30		μV/°C

5.11.6 Timer_A

Table 5-13 lists the characteristics of Timer_A.

Table 5-13. Timer A

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

DADAMETED	TEST SOMETIONS	.,		T\/D		
PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{TA} Timer_A input clock frequency	Internal: SMCLK, ACLK External: TACLK Duty cycle = 50% ±10%	2 V, 3 V			16	MHz

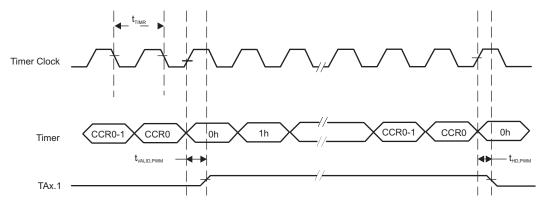


Figure 5-11. Timer PWM Mode

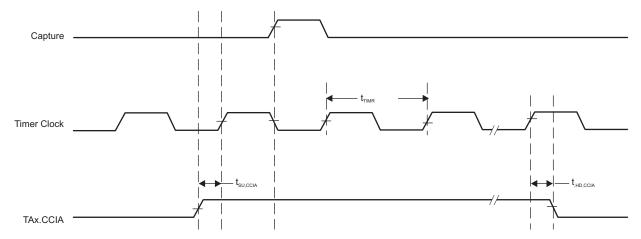


Figure 5-12. Timer Capture Mode



5.11.7 eUSCI

Table 5-14 lists the supported frequencies of the eUSCI in UART mode.

Table 5-14. eUSCI (UART Mode) Clock Frequency

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN MAX	UNIT
f _{eUSCI}	eUSCI input clock frequency	Internal: SMCLK, MODCLK External: UCLK Duty cycle = 50% ±10%	2 V, 3 V	16	MHz
f _{BITCLK}	BITCLK clock frequency (equals baud rate in Mbaud)		2 V, 3 V	5	MHz

Table 5-15 lists the characteristics of the eUSCI in UART mode.

Table 5-15. eUSCI (UART Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
t _t		UCGLITx = 0		12	ns
	UART receive deglitch time (1)	UCGLITx = 1	2 V, 3 V	40	
		UCGLITx = 2		68	
		UCGLITx = 3		110	

⁽¹⁾ Pulses on the UART receive input (UCxRX) shorter than the UART receive deglitch time are suppressed. To ensure that pulses are correctly recognized, their duration should exceed the maximum specification of the deglitch time.

Table 5-16 lists the supported frequencies of the eUSCI in SPI master mode.

Table 5-16. eUSCI (SPI Master Mode) Clock Frequency

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
f _{eUSCI}	ALISCI INDUIT CIOCK TRADITANCY	Internal: SMCLK, MODCLK Duty cycle = 50% ±10%		8	MHz



Table 5-17 lists the characteristics of the eUSCI in SPI master mode.

Table 5-17. eUSCI (SPI Master Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

PARAMETER		TEST CONDITIONS V _C		MIN	MAX	UNIT
t _{STE,LEAD}	STE lead time, STE active to clock	UCSTEM = 0, UCMODEx = 01 or 10	4			UCxCLK
		UCSTEM = 1, UCMODEx = 01 or 10		I		cycles
t _{STE,LAG}	STE lag time, last clock to STE inactive	UCSTEM = 0, UCMODEx = 01 or 10		4		UCxCLK cycles
		UCSTEM = 1, UCMODEx = 01 or 10		. I		
t _{SU,MI}	SOMI input data setup time		2 V	48		ns
			3 V	37		115
t _{HD,MI}	SOMI input data hold time		2 V	0		
			3 V	0		ns
t _{VALID,MO}	SIMO output data valid time ⁽²⁾	UCLK edge to SIMO valid,	2 V		20	ns
		$C_L = 20 \text{ pF}$	3 V		20	
t _{HD,MO}	SIMO output data hold time ⁽³⁾	C _L = 20 pF	2 V	-6		
			3 V	-5		ns

⁽¹⁾

 $f_{UCXCLK} = 1/2t_{LO/HI} \ \ \text{with} \ \ t_{LO/HI} = \max(t_{VALID,MO(eUSCI)} + t_{SU,SI(Slave)}, t_{SU,MI(eUSCI)} + t_{VALID,SO(Slave)})$ For the slave parameters $t_{SU,SI(Slave)}$ and $t_{VALID,SO(Slave)}$, see the SPI parameters of the attached slave. Specifies the time to drive the next valid data to the SIMO output after the output changing UCLK clock edge. See the timing diagrams in Figure 5-13 and Figure 5-14.

⁽³⁾ Specifies how long data on the SIMO output is valid after the output changing UCLK clock edge. Negative values indicate that the data on the SIMO output can become invalid before the output changing clock edge observed on UCLK. See the timing diagrams in Figure 5-13 and Figure 5-14.



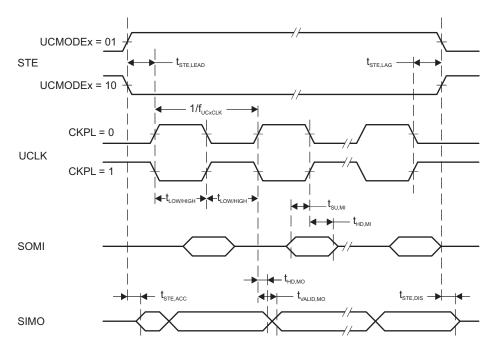


Figure 5-13. SPI Master Mode, CKPH = 0

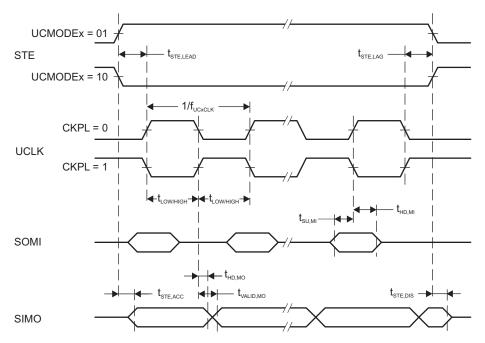


Figure 5-14. SPI Master Mode, CKPH = 1



Table 5-18 lists the characteristics of the eUSCI in SPI slave mode.

Table 5-18. eUSCI (SPI Slave Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	MAX	UNIT
t _{STE,LEAD}	STE lead time, STE active to clock		2 V	55		ns
			3 V	45		
t _{STE,LAG}	STE lag time, Last clock to STE inactive		2 V	20		20
			3 V	20		ns
	STE access time, STE active to SOMI data out		2 V		65	20
t _{STE,ACC}			3 V		40	ns
	STE disable time, STE inactive to SOMI high impedance		2 V		40	
t _{STE,DIS}			3 V		35	ns
	SIMO input data setup time		2 V	8		ns
t _{SU,SI}			3 V	6		
	SIMO input data hold time		2 V	12		
t _{HD,SI}			3 V	12		ns
t _{VALID,SO}	SOMI output data valid time ⁽²⁾	UCLK edge to SOMI valid, 2 V	68			
	Solvii output data valid time	$C_L = 20 \text{ pF}$	3 V		42	ns
t _{HD,SO}	SOMI output data hold time (3)	C 20 pF	2 V	5		ns
		$C_L = 20 \text{ pF}$	3 V	5		

 $f_{UCxCLK} = 1/2 t_{LO/HI} \text{ with } t_{LO/HI} \geq \max(t_{VALID,MO(Master)} + t_{SU,SI(eUSCI)}, t_{SU,MI(Master)} + t_{VALID,SO(eUSCI)})$ For the master parameters $t_{SU,MI(Master)}$ and $t_{VALID,MO(Master)}$, see the SPI parameters of the attached master. Specifies the time to drive the next valid data to the SOMI output after the output changing UCLK clock edge. See the timing diagrams (1)

in Figure 5-15 and Figure 5-16.

⁽³⁾ Specifies how long data on the SOMI output is valid after the output changing UCLK clock edge. See the timing diagrams in Figure 5-15 and Figure 5-16.

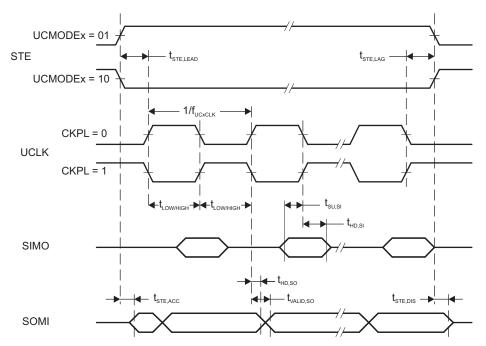


Figure 5-15. SPI Slave Mode, CKPH = 0

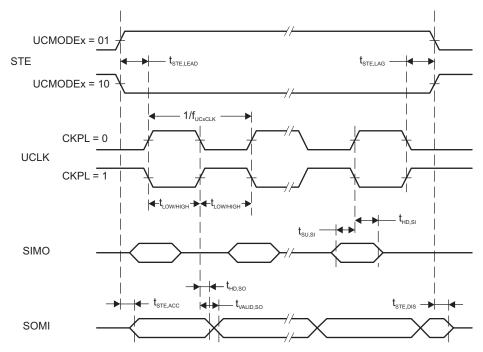


Figure 5-16. SPI Slave Mode, CKPH = 1



Table 5-19 lists the characteristics of the eUSCI in I²C mode.

Table 5-19. eUSCI (I²C Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5-17)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{eUSCI}	eUSCI input clock frequency	Internal: SMCLK, MODCLK External: UCLK Duty cycle = 50% ±10%				16	MHz
f _{SCL}	SCL clock frequency		2 V, 3 V	0		400	kHz
	Hold time (repeated) START	f _{SCL} = 100 kHz	2.1/ 2.1/	4.0			μs
t _{HD,STA}		f _{SCL} > 100 kHz	2 V, 3 V	0.6			
	Setup time for a repeated START	f _{SCL} = 100 kHz	21/ 21/	4.7			μs
t _{SU,STA}		f _{SCL} > 100 kHz	2 V, 3 V	0.6			
$t_{HD,DAT}$	Data hold time		2 V, 3 V	0			ns
t _{SU,DAT}	Data setup time		2 V, 3 V	250			ns
	Setup time for STOP	f _{SCL} = 100 kHz	2 V, 3 V	4.0			μs
t _{SU,STO}		f _{SCL} > 100 kHz		0.6			
	Pulse duration of spikes suppressed by	UCGLITx = 0	50		600		
		UCGLITx = 1	2.1/ 2.1/	25		300	20
t _{SP}	input filter	UCGLITx = 2	2 V, 3 V	12.5		150	ns
		UCGLITx = 3		6.3		75	
t _{TIMEOUT}	Clock low time-out	UCCLTOx = 1			27		
		UCCLTOx = 2	2 V, 3 V	30		ms	
		UCCLTOx = 3			33		

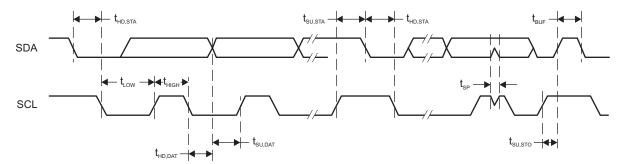


Figure 5-17. I²C Mode Timing



5.11.8 ADC

Table 5-20 lists the characteristics of the ADC power supply and input range conditions.

Table 5-20. ADC, Power Supply and Input Range Conditions

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
DV _{CC}	ADC supply voltage			2.0		3.6	V
V _(Ax)	Analog input voltage range	All ADC pins		0		DV_CC	V
	Operating supply current into	f _{ADCCLK} = 5 MHz, ADCON = 1,	2 V		185		
I _{ADC}	DVCC terminal, reference current not included, repeat- single-channel mode	REFON = 0, SHT0 = 0, SHT1 = 0, ADCDIV = 0, ADCCONSEQx = 10b	3 V		207		μΑ
C _I	Input capacitance	Only one terminal Ax can be selected at one time from the pad to the ADC capacitor array, including wiring and pad	2.2 V		2.5	3.5	pF
R _I	Input MUX ON resistance	$DV_{CC} = 2 \text{ V}, 0 \text{ V} = V_{Ax} = DV_{CC}$				36	kΩ

Table 5-21 lists the ADC 10-bit timing parameters.

Table 5-21. ADC, 10-Bit Timing Parameters

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{ADCCLK}		For specified performance of ADC linearity parameters	2 V to 3.6 V	0.45	5	5.5	MHz
f _{ADCOSC}	Internal ADC oscillator (MODOSC)	ADCDIV = 0, f _{ADCCLK} = f _{ADCOSC}	2 V to 3.6 V	3.8	4.8	5.8	MHz
tconvert	Conversion time	REFON = 0, Internal oscillator, 10 ADCCLK cycles, 10-bit mode, f _{ADCOSC} = 4.5 MHz to 5.5 MHz	2 V to 3.6 V	2.18		2.67	μs
		External f_{ADCCLK} from ACLK, MCLK, or SMCLK, ADCSSEL $\neq 0$	2 V to 3.6 V		12 x 1 / f _{ADCCLK}		
t _{ADCON}	Turnon settling time of the ADC	The error in a conversion started after t _{ADCON} is less than ±0.5 LSB. Reference and input signal are already settled.				100	ns
t _{Sample}	Sampling time	R_S = 1000 Ω , R_I = 36000 Ω , C_I = 3.5 pF. Approximately 8 Tau (t) are required for an error of less than ±0.5 LSB.	3 V	2.0			μs



Table 5-22 lists the ADC 10-bit linearity parameters.

Table 5-22. ADC, 10-Bit Linearity Parameters

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
_	Integral linearity error (10-bit mode)	Veref+ reference	2.4 V to 3.6 V	-2		2	LSB
Eı	Integral linearity error (8-bit mode)	verei+ reference	2.0 V to 3.6 V	-2		2	LOD
_	Differential linearity error (10-bit mode)	Manafa mafanana	2.4 V to 3.6 V	-1		1	LSB
E _D	Differential linearity error (8-bit mode)	Veref+ reference	2.0 V to 3.6 V	-1		1	LSB
_	Offset error (10-bit mode)	Veref+ reference	2.4 V to 3.6 V	-6.5		6.5	mV
Eo	Offset error (8-bit mode)	verei+ reference	2.0 V to 3.6 V	-6.5		6.5	IIIV
	Coin array (40 hit made)	Veref+ as reference	241/4-261/	-2.0		2.0	LSB
_	Gain error (10-bit mode)	Internal 1.5-V reference	2.4 V to 3.6 V	-3.0%		3.0%	
E _G	Onia a man (O hit and da)	Veref+ as reference	2.0 V to 3.6 V	-2.0		2.0	LSB
	Gain error (8-bit mode)	Internal 1.5-V reference	2.0 V to 3.6 V	-3.0%		3.0%	
	T	Veref+ as reference	0.41/4. 0.01/4	-2.0		2.0	LSB
_	Total unadjusted error (10-bit mode)	Internal 1.5-V reference	2.4 V to 3.6 V	-3.0%		3.0%	
E _T	Tatal and direct diament (0 hit and da)	Veref+ as reference	0.03/15-0.03/	-2.0		2.0	LSB
	Total unadjusted error (8-bit mode)	Internal 1.5-V reference	2.0 V to 3.6 V	-3.0%		3.0%	
V _{SENSOR}	See ⁽¹⁾	ADCON = 1, INCH = 0Ch, T _A = 0°C	3 V		913		mV
TC _{SENSOR}	See (2)	ADCON = 1, INCH = 0Ch	3 V		3.35		mV/°C
t _{SENSOR}	Sample time required if channel 12 is	ADCON = 1, INCH = 0Ch, Error of conversion result ≤1 LSB, AM and all LPMs above LPM3	3 V	30			μs
(sample)	selected (3)	ADCON = 1, INCH = 0Ch, Error of conversion result ≤1 LSB, LPM3	3 V	100			·

⁽¹⁾ The temperature sensor offset can vary significantly. TI recommends a single-point calibration to minimize the offset error of the built-in temperature sensor.

The device descriptor structure contains calibration values for 30°C and 85°C for each available reference voltage level. The sensor voltage can be computed as $V_{SENSOR} = TC_{SENSOR} \times (Temperature, °C) + V_{SENSOR}$, where TC_{SENSOR} and V_{SENSOR} can be computed from the calibration values for higher accuracy.

The typical equivalent impedance of the sensor is 700 k Ω . The sample time required includes the sensor on time, $t_{SENSOR(on)}$.



5.11.9 CapTIvate

Table 5-23 lists the characteristics of the CapTIvate module.

Table 5-23. CapTIvate Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{REG}	Reference voltage output		1.5	1.55	1.6	V
C _{REG}	External buffer capacitor	ESR ≤ 200 mΩ	0.8	1	1.2	μF
C _{ELECTRODE}	Maximum capacitance of all external electrodes on all CapTlvate blocks	Running a conversion at 4 MHz			300	pF
t _{WAKEUP,COLD}	Voltage regulator wake-up time	LDO completely off then turned on		700		μs
t _{WAKEUP,WARM}	Voltage regulator wake-up time	LDO in low-power mode then turned on		260		μs
f _{CAPCLK}	CapTIvate oscillator frequency, nominal	T _A = 25°C, CAPCLK0, FREQSHFT = 00b		16		MHz
DC _{CAPCLK}	CapTIvate oscillator duty cycle	Excluding first clock cycle, $DC = t_{high} \times f$	40%	50%	60%	

Table 5-24 lists the signal-to-noise ratio of the CapTIvate module.

Table 5-24. CapTIvate Signal-to-Noise Ratio Characteristics

over operating free-air temperature range from -40°C to 105°C ambient (T_A), unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		T_A = 25°C, C_t > 0.5 pF, C_p < 20 pF, >2.5% change in capacitance ⁽²⁾	5:1	36:1		
SNR	Signal-to-noise ratio ⁽¹⁾	$T_A = 0$ °C, $C_t > 0.5$ pF, $C_p < 20$ pF, >2.5% change in capacitance ⁽²⁾		28:1		
		$T_A = -40$ °C, $C_t > 0.5$ pF, $C_p < 20$ pF, >2.5% change in capacitance $^{(2)}$		19:1		

⁽¹⁾ SNR is defined as the ratio of the measured change in electrode capacitance due to a touch compared with the measured change in capacitance due to the device noise floor. For additional detail on SNR in capacitive sensing applications and how to measure it in your system, see Sensitivity, SNR, and Design Margin in Capacitive Touch Applications.

system, see Sensitivity, SNR, and Design Margin in Capacitive Touch Applications.

(2) C_t represents the increase or decrease in electrode capacitance due to a touch. C_p represents the inherent parasitic capacitance of the sensing electrode that is present when no touch is applied. Therefore, the touch signal is defined as C_t/C_p, expressed as a percent change in capacitance. Increasing C_t or decreasing C_p increases signal.



5.11.10 FRAM

Table 5-25 lists the characteristics of the FRAM.

Table 5-25. FRAM

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Read and write endurance		10 ¹⁵			cycles
		$T_J = 25^{\circ}C$	100			
t _{Retention}	Data retention duration	$T_J = 70^{\circ}C$	40			years
		$T_J = 85^{\circ}C$	10			
I _{WRITE}	Current to write into FRAM			I _{READ} ⁽¹⁾		nA
I _{ERASE}	Erase current			N/A ⁽²⁾		nA
t _{WRITE}	Write time			t _{READ} (3)		ns
	Dood time	NWAITSx = 0		1 / f _{SYSTEM} ⁽⁴⁾		20
t _{READ}	Read time	NWAITSx = 1		2 / f _{SYSTEM} ⁽⁴⁾		ns

Writing to FRAM does not require a setup sequence or additional power when compared to reading from FRAM. The FRAM read current I_{READ} is included in the active mode current consumption parameter I_{AM,FRAM}.

40

FRAM does not require a special erase sequence.

Writing into FRAM is as fast as reading.

The maximum read (and write) speed is specified by f_{SYSTEM} using the appropriate wait state settings (NWAITSx).



5.11.11 Debug and Emulation

Table 5-26 lists the characteristics of the 2-wire SBW interface.

Table 5-26. JTAG, Spy-Bi-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5-18)

	PARAMETER	V _{cc}	MIN	TYP	MAX	UNIT
f _{SBW}	Spy-Bi-Wire input frequency	2 V, 3 V	0		8	MHz
t _{SBW,Low}	Spy-Bi-Wire low clock pulse duration	2 V, 3 V	0.028		15	μs
t _{SU, SBWTDIO}	SBWTDIO setup time (before falling edge of SBWTCK in TMS and TDI slot, Spy-Bi-Wire)	2 V, 3 V	4			ns
t _{HD} , SBWTDIO	SBWTDIO hold time (after rising edge of SBWTCK in TMS and TDI slot, Spy-Bi-Wire)	2 V, 3 V	19			ns
t _{Valid} , SBWTDIO	SBWTDIO data valid time (after falling edge of SBWTCK in TDO slot, Spy-Bi-Wire)	2 V, 3 V			31	ns
t _{SBW, En}	Spy-Bi-Wire enable time (TEST high to acceptance of first clock edge) (1)	2 V, 3 V			110	μs
t _{SBW,Ret}	Spy-Bi-Wire return to normal operation time ⁽²⁾	2 V, 3 V	15		100	μs
R _{internal}	Internal pulldown resistance on TEST	2 V, 3 V	20	35	50	kΩ

- (1) Tools that access the Spy-Bi-Wire interface must wait for the t_{SBW,En} time after pulling the TEST/SBWTCK pin high before applying the first SBWTCK clock edge.
- (2) Maximum t_{SBW,Ret} time after pulling or releasing the TEST/SBWTCK pin low until the Spy-Bi-Wire pins revert from their Spy-Bi-Wire function to their application function. This time applies only if the Spy-Bi-Wire mode is selected.

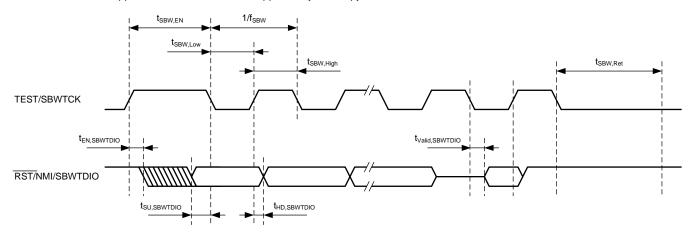


Figure 5-18. JTAG Spy-Bi-Wire Timing

Table 5-27 lists the characteristics of the 4-wire JTAG interface.

Table 5-27. JTAG, 4-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5-19)

	PARAMETER	V _{cc}	MIN	TYP	MAX	UNIT
f _{TCK}	TCK input frequency ⁽¹⁾	2 V, 3 V	0		10	MHz
t _{TCK,Low}	TCK low clock pulse duration	2 V, 3 V	15			ns
t _{TCK,High}	TCK high clock pulse duration	2 V, 3 V	15			ns
t _{SU,TMS}	TMS setup time (before rising edge of TCK)	2 V, 3 V	11			ns
t _{HD,TMS}	TMS hold time (after rising edge of TCK)	2 V, 3 V	3			ns
t _{SU,TDI}	TDI setup time (before rising edge of TCK)	2 V, 3 V	13			ns
t _{HD,TDI}	TDI hold time (after rising edge of TCK)	2 V, 3 V	5			ns
t _{Z-Valid,TDO}	TDO high impedance to valid output time (after falling edge of TCK)	2 V, 3 V			26	ns
t _{Valid,TDO}	TDO to new valid output time (after falling edge of TCK)	2 V, 3 V			26	ns
t _{Valid-Z,TDO}	TDO valid to high-impedance output time (after falling edge of TCK)	2 V, 3 V			26	ns
t _{JTAG,Ret}	Spy-Bi-Wire return to normal operation time		15		100	μs
R _{internal}	Internal pulldown resistance on TEST	2 V, 3 V	20	35	50	kΩ

(1) f_{TCK} may be restricted to meet the timing requirements of the module selected.

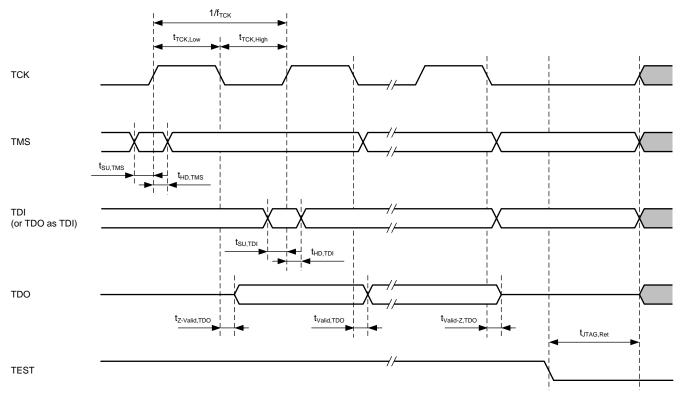


Figure 5-19. JTAG 4-Wire Timing

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6 Detailed Description

6.1 Overview

The MSP430FR2522 and MSP430FR2512 ultra-low-power MCUs are FRAM-based MCUs with integrated high-performance charge-transfer CapTIvate technology in ultra-low-power high-reliability high-flexibility MCUs. The MSP430FR2522 and MSP430FR2512 MCUs feature up to 8 self-capacitance or 16 mutual-capacitance electrodes, proximity sensing, and high accuracy up to 1-fF detection. The MCUs also include two 16-bit timers, eUSCIs that support UART, SPI, and I²C, a hardware multiplier, an RTC module, and a high-performance 10-bit ADC.

6.2 CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter (PC), stack pointer (SP), status register (SR), and constant generator (CG), respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses. Peripherals can be handled with all instructions.

6.3 Operating Modes

The MSP430 has one active mode and several software-selectable low-power modes of operation (see Table 6-1). An interrupt event can wake the MCU from low-power mode LPM0, LPM3 or LPM4, service the request, and restore the MCU back to the low-power mode on return from the interrupt program. Low-power modes LPM3.5 and LPM4.5 disable the core supply to minimize power consumption.

NOTE

XT1CLK and VLOCLK can be active during LPM4 mode if requested by low-frequency peripherals, such as RTC, WDT, and CapTlvate.

Table 6-1. Operating Modes

		AM	LPM0	LPM3	LPM4	LPM3.5	LPM4.5
	MODE	ACTIVE MODE (FRAM ON)	CPU OFF	STANDBY	OFF	ONLY RTC	SHUTDOWN
Maximum system clock		16 MHz	16 MHz	40 kHz	0	40 kHz	0
Power consumption at 25°C, 3 V		126 μA/MHz	40 μA/MHz	1.7 µA/button average with 8-Hz scan	0.49 μA without SVS	0.73 µA with RTC counter only in LFXT	16 nA without SVS
Wake-up time		N/A	Instant	10 µs	10 µs	350 µs	350 µs
Wake-up ever	nts	N/A	All	All	CapTlvate I/O	RTC I/O	I/O
	Regulator	Full Regulation	Full Regulation	Partial Power Down	Partial Power Down	Partial Power Down	Power Down
Power	SVS	On	On	Optional	Optional	Optional	Optional
	Brownout	On	On	On	On	On	On
	MCLK	Active	Off	Off	Off	Off	Off
	SMCLK	Optional	Optional	Off	Off	Off	Off
	FLL	Optional	Optional	Off	Off	Off	Off
	DCO	Optional	Optional	Off	Off	Off	Off
Q1 (1)	MODCLK	Optional	Optional	Off	Off	Off	Off
Clock ⁽¹⁾	REFO	Optional	Optional	Optional	Off	Off	Off
	ACLK	Optional	Optional	Optional	Off	Off	Off
	XT1CLK	Optional	Optional	Optional	Off	Optional	Off
	VLOCLK	Optional	Optional	Optional	Off	Optional	Off
	CapTIvate MODCLK	Optional	Optional	Optional	Off	Off	Off
	CPU	On	Off	Off	Off	Off	Off
0	FRAM	On	On	Off	Off	Off	Off
Core	RAM	On	On	On	On	Off	Off
	Backup memory ⁽²⁾	On	On	On	On	On	Off
	Timer0_A3	Optional	Optional	Optional	Off	Off	Off
	Timer1_A3	Optional	Optional	Optional	Off	Off	Off
	WDT	Optional	Optional	Optional	Off	Off	Off
	eUSCI_A0	Optional	Optional	Optional	Off	Off	Off
Peripherals	eUSCI_B0	Optional	Optional	Optional	Off	Off	Off
	CRC	Optional	Optional	Off	Off	Off	Off
	ADC	Optional	Optional	Optional	Off	Off	Off
	RTC	Optional	Optional	Optional	Off	Optional	Off
	CapTlvate	Optional	Optional	Optional	Off	Off	Off
I/O	General-purpose digital input/output	On	Optional	State Held	State Held	State Held	State Held

⁽¹⁾ The status shown for LPM4 applies to internal clocks only.

6.4 Interrupt Vector Addresses

The interrupt vectors and the power-up start address are in the address range 0FFFFh to 0FF80h (see Table 6-2). The vector contains the 16-bit address of the appropriate interrupt-handler instruction sequence.

⁽²⁾ Backup memory contains 32 bytes of register space in peripheral memory. See Table 6-20 and Table 6-35 for its memory allocation.



Table 6-2. Interrupt Sources, Flags, and Vectors

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
System Reset Power up, Brownout, Supply supervisor External reset RST Watchdog time-out, Key violation FRAM uncorrectable bit error detection Software POR, BOR FLL unlock error	SVSHIFG PMMRSTIFG WDTIFG PMMPORIFG, PMMBORIFG SYSRSTIV FLLUNLOCKIFG	Reset	FFFEh	63, Highest
System NMI Vacant memory access JTAG mailbox FRAM access time error FRAM bit error detection	VMAIFG JMBINIFG, JMBOUTIFG CBDIFG, UBDIFG	Nonmaskable	FFFCh	62
User NMI External NMI Oscillator fault	NMIIFG OFIFG	Nonmaskable	FFFAh	61
Timer0_A3	TA0CCR0 CCIFG0	Maskable	FFF8h	60
Timer0_A3	TA0CCR1 CCIFG1, TA0CCR2 CCIFG2, TA0IFG (TA0IV)	Maskable	FFF6h	59
Timer1_A3	TA1CCR0 CCIFG0	Maskable	FFF4h	58
Timer1_A3	TA1CCR1 CCIFG1, TA1CCR2 CCIFG2, TA1IFG (TA1IV)	Maskable	FFF2h	57
RTC	RTCIFG	Maskable	FFF0h	56
Watchdog timer interval mode	WDTIFG	Maskable	FFEEh	55
eUSCI_A0 receive or transmit	UCTXCPTIFG, UCSTTIFG, UCRXIFG, UCTXIFG (UART mode) UCRXIFG, UCTXIFG (SPI mode) (UCA0IV)	Maskable	FFECh	54
eUSCI_B0 receive or transmit	UCBORXIFG, UCBOTXIFG (SPI mode) UCALIFG, UCNACKIFG, UCSTTIFG, UCSTPIFG, UCRXIFG0, UCTXIFG0, UCRXIFG1, UCTXIFG1, UCRXIFG2, UCTXIFG2, UCRXIFG3, UCTXIFG3, UCCNTIFG, UCBIT9IFG (I ² C mode) (UCB0IV)	Maskable	FFEAh	53
ADC	ADCIFG0, ADCINIFG, ADCLOIFG, ADCHIIFG, ADCTOVIFG, ADCOVIFG (ADCIV)	Maskable	FFE8h	52
P1	P1IFG.0 to P1IFG.7 (P1IV)	Maskable	FFE6h	51
P2	P2IFG.0 to P2IFG.6 (P2IV)	Maskable	FFE4h	50
CapTlvate	(See CapTivate Design Center for details)	Maskable	FFE2h	49, Lowest
Reserved	Reserved	Maskable	FFE0h-FF88h	

Table 6-3. Signatures

SIGNATURE	WORD ADDRESS
BSL Signature2	0FF86h
BSL Signature1	0FF84h
JTAG Signature2	0FF82h
JTAG Signature1	0FF80h

6.5 Bootloader (BSL)

The BSL lets users program the FRAM or RAM using either the UART serial interface or the I²C interface. Access to the MCU memory through the BSL is protected by an user-defined password. Use of the BSL requires four pins (see Table 6-4 and Table 6-5). The BSL entry requires a specific entry sequence on the RST/NMI/SBWTDIO and TEST/SBWTCK pins. This device can support the blank device detection automatically to invoke the BSL with bypass this special entry sequence for saving time and on board programmable. For the complete description of the feature of the BSL, see the MSP430 FRAM Device Bootloader (BSL) User's Guide.

Table 6-4. UART BSL Pin Requirements and Functions

DEVICE SIGNAL	BSL FUNCTION
RST/NMI/SBWTDIO	Entry sequence signal
TEST/SBWTCK	Entry sequence signal
P1.4	Data transmit
P1.5	Data receive
DVCC	Power supply
DVSS	Ground supply

Table 6-5. I²C BSL Pin Requirements and Functions

DEVICE SIGNAL	BSL FUNCTION
RST/NMI/SBWTDIO	Entry sequence signal
TEST/SBWTCK	Entry sequence signal
P1.2	Data transmit and receive
P1.3	Clock
DVCC	Power supply
DVSS	Ground supply

6.6 JTAG Standard Interface

The MSP low-power microcontrollers support the standard JTAG interface, which requires four signals for sending and receiving data. The JTAG signals are shared with general-purpose I/O. The TEST/SBWTCK pin enables the JTAG signals. In addition to these signals, the RST/NMI/SBWTDIO is required to interface with MSP430 development tools and device programmers. Table 6-6 lists the JTAG pin requirements. For further details on interfacing to development tools and device programmers, see the MSP430 Hardware Tools User's Guide. For details on using the JTAG interface, see MSP430 Programming With the JTAG Interface.

Table 6-6. JTAG Pin Requirements and Function

DEVICE SIGNAL	DIRECTION	JTAG FUNCTION	
P1.4//TCK	IN JTAG clock ii		
P1.5//TMS	IN	JTAG state control	
P1.6//TDI/TCLK	IN	JTAG data input, TCLK input	
P1.7//TDO			
TEST/SBWTCK			
RST/NMI/SBWTDIO	IN	External reset	
DVCC	DVCC – Pov		
DVSS	_	Ground supply	



6.7 Spy-Bi-Wire Interface (SBW)

The MSP low-power microcontrollers support the 2-wire SBW interface. SBW can be used to interface with MSP development tools and device programmers. Table 6-7 lists the SBW interface pin requirements. For further details on interfacing to development tools and device programmers, see the MSP430 Hardware Tools User's Guide. For details on using the SBW interface, see the MSP430 Programming With the JTAG Interface.

Table 6-7. Spy-Bi-Wire Pin Requirements and Functions

DEVICE SIGNAL	DIRECTION	SBW FUNCTION
TEST/SBWTCK	IN	Spy-Bi-Wire clock input
RST/NMI/SBWTDIO	IN, OUT	Spy-Bi-Wire data input and output
DVCC	-	Power supply
DVSS	I	Ground supply

6.8 FRAM

The FRAM can be programmed using the JTAG port, SBW, the BSL, or in-system by the CPU. Features of the FRAM include:

- Byte and word access capability
- · Programmable wait state generation
- Error correction coding (ECC)

6.9 Memory Protection

The device features memory protection for user access authority and write protection, including options to:

- Secure the whole memory map to prevent unauthorized access from JTAG port or BSL, by writing JTAG and BSL signatures using the JTAG port, SBW, the BSL, or in-system by the CPU.
- Enable write protection to prevent unwanted write operation to FRAM contents by setting the control
 bits in the System Configuration 0 register. For detailed information, see the SYS chapter in the
 MP430FR4xx and MP430FR2xx Family User's Guide.

6.10 Peripherals

Peripherals are connected to the CPU through data, address, and control buses. All peripherals can be handled by using all instructions in the memory map. For complete module description, see the MP430FR4xx and MP430FR2xx Family User's Guide.

6.10.1 Power-Management Module (PMM)

The PMM includes an integrated voltage regulator that supplies the core voltage to the device. The PMM also includes supply voltage supervisor (SVS) and brownout protection. The brownout reset circuit (BOR) is implemented to provide the proper internal reset signal to the device during power on and power off. The SVS circuitry detects if the supply voltage drops below a user-selectable safe level. SVS circuitry is available on the primary supply.

The device contains two on-chip reference: 1.5 V for internal reference and 1.2 V for external reference.

The 1.5-V reference is internally connected to ADC channel 13. DVCC is internally connected to ADC channel 15. When DVCC is set as the reference voltage for ADC conversion, the DVCC can be easily represent as Equation 1 by using ADC sampling 1.5-V reference without any external components support.

(1)



A 1.2-V reference voltage can be buffered, when EXTREFEN = 1 on PMMCTL2 register, and it can be output to P1.1/../A1/VREF+, meanwhile the ADC channel 1 can also be selected to monitor this voltage. For more detailed information, see the MSP430FR4xx and MSP430FR2xx Family User's Guide.

6.10.2 Clock System (CS) and Clock Distribution

The clock system includes a 32-kHz crystal oscillator (XT1), an internal very-low-power low-frequency oscillator (VLO), an integrated 32-kHz RC oscillator (REFO), an integrated internal digitally controlled oscillator (DCO) that may use frequency-locked loop (FLL) locking with internal or external 32-kHz reference clock, and an on-chip asynchronous high-speed clock (MODOSC). The clock system is designed for cost-effective designs with minimal external components. A fail-safe mechanism is included for XT1. The clock system module offers the following clock signals.

- Main Clock (MCLK): The system clock used by the CPU and all relevant peripherals accessed by the bus. All clock sources except MODOSC can be selected as the source with a predivider of 1, 2, 4, 8, 16, 32, 64, or 128.
- Sub-Main Clock (SMCLK): The subsystem clock used by the peripheral modules. SMCLK derives from the MCLK with a predivider of 1, 2, 4, or 8. This means SMCLK is always equal to or less than MCLK.
- Auxiliary Clock (ACLK): This clock is derived from the external XT1 clock or internal REFO clock up to 40 kHz.

All peripherals may have one or several clock sources depending on specific functionality. Table 6-8 lists the clock distribution used in this device.

Table 6-8. Clock Distribution

	CLOCK SOURCE SELECT BITS	MCLK	SMCLK	ACLK	MODCLK	XT1CLK	VLOCLK	EXTERNAL PIN
Frequency Range		DC to 16 MHz	DC to 16 MHz	DC to 40 kHz	5 MHz ±10%	DC to 40 kHz	10 kHz ±50%	-
CPU	N/A	Default	_	-	-	-	-	_
FRAM	N/A	Default	_	-	-	-	-	_
RAM	N/A	Default	_	-	-	-	-	_
CRC	N/A	Default	_	-	-	-	-	_
I/O	N/A	Default	_	-	-	-	-	_
TA0	TASSEL	-	10b	01b	-	-	11b	00b (TA0CLK pin)
TA1	TASSEL	-	10b	01b	-	-	-	00b (TA1CLK pin)
eUSCI_A0	UCSSEL	-	10b or 11b	01b	-	-	-	00b (UCA0CLK pin)
eUSCI_B0	UCSSEL	-	10b or 11b	01b	-	_	-	00b (UCB0CLK pin)
WDT	WDTSSEL	-	00b	01b	-	_	10b	_
ADC	ADCSSEL	-	10b or 11b	01b	00b	_	-	-
CapTIvate	CAPTSSEL	-	_	00b	-	-	01b	-
RTC	RTCSS	-	01b ⁽¹⁾	01b ⁽¹⁾	-	10b	11b	_

⁽¹⁾ Controlled by the RTCCKSEL bit in the SYSCFG2 register



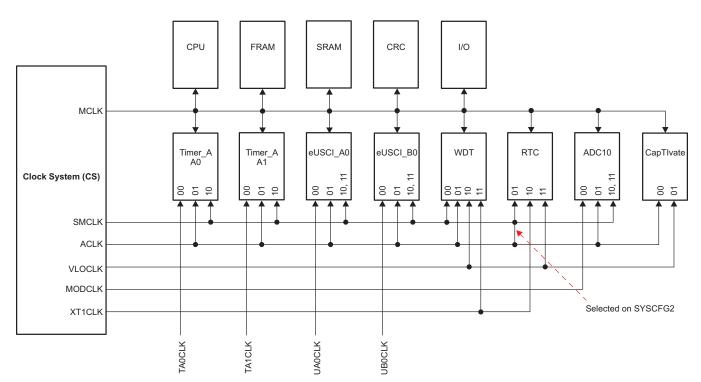


Figure 6-1. Clock Distribution Block Diagram

6.10.3 General-Purpose Input/Output Port (I/O)

Up to 15 I/O ports are implemented.

- P1 implements 8 bits, and P2 implements 7 bits.
- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt conditions is possible.
- Programmable pullup or pulldown on all ports.
- Edge-selectable interrupt and LPMx.5 wake-up input capability are available for P1 and P2.
- Read and write access to port-control registers is supported by all instructions.
- Ports can be accessed byte-wise or word-wise as a pair.
- CapTIvate functionality is supported on all CAPx.y pins.

NOTE

Configuration of digital I/Os after BOR reset

To prevent any cross currents during start-up of the device, all port pins are high-impedance with Schmitt triggers and module functions disabled. To enable the I/O functions after a BOR reset, the ports must be configured first and then the LOCKLPM5 bit must be cleared. For details, see the *Configuration After Reset* section in the Digital I/O chapter of the MP430FR4xx and MP430FR2xx Family User's Guide.

6.10.4 Watchdog Timer (WDT)

The primary function of the WDT module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be configured as an interval timer and can generate interrupts at selected time intervals. Table 6-9 lists the system clocks that can be used to source the WDT.

Table 6-9. WDT Clocks

WDTSSEL	NORMAL OPERATION (WATCHDOG AND INTERVAL TIMER MODE)
00	SMCLK
01	ACLK
10	VLOCLK
11	Reserved



6.10.5 System (SYS) Module

The SYS module handles many of the system functions within the device. These features include power-on reset (POR) and power-up clear (PUC) handling, NMI source selection and management, reset interrupt vector generators, bootloader entry mechanisms, and configuration management (device descriptors). The SYS module also includes a data exchange mechanism through SBW called a JTAG mailbox mail box that can be used in the application. Table 6-10 summarizes the interrupts that are managed by the SYS module.

Table 6-10. System Module Interrupt Vector Registers

INTERRUPT VECTOR REGISTER	ADDRESS	INTERRUPT EVENT	VALUE	PRIORITY
		No interrupt pending	00h	
		Brownout (BOR)	02h	Highest
		RSTIFG RST/NMI (BOR)	04h	
		PMMSWBOR software BOR (BOR)	06h	
		LPMx.5 wakeup (BOR)	08h	
		Security violation (BOR)	0Ah	
		Reserved	0Ch	
		SVSHIFG SVSH event (BOR)	0Eh	
		Reserved	10h	
SYSRSTIV, System Reset	015Eh	Reserved	12h	
		PMMSWPOR software POR (POR)	14h	
		WDTIFG watchdog time-out (PUC)	16h	
		WDTPW password violation (PUC)	18h	
		FRCTLPW password violation (PUC)	1Ah	
		Uncorrectable FRAM bit error detection	1Ch	
		Peripheral area fetch (PUC)	1Eh	
		PMMPW PMM password violation (PUC)	20h	
		FLL unlock (PUC)	24h	
		Reserved	22h, 26h to 3Eh	Lowest
		No interrupt pending	00h	
		SVS low-power reset entry	02h	Highest
		Uncorrectable FRAM bit error detection	04h	
		Reserved	06h	
		Reserved	08h	
		Reserved	0Ah	
		Reserved	0Ch	
SYSSNIV, System NMI	015Ch	Reserved	0Eh	
		Reserved	10h	
		VMAIFG vacant memory access	12h	
		JMBINIFG JTAG mailbox input	14h	
		JMBOUTIFG JTAG mailbox output	16h	
		Correctable FRAM bit error detection	18h	
		Reserved	1Ah to 1Eh	Lowest
		No interrupt pending	00h	
		NMIIFG NMI pin or SVS _H event	02h	Highest
SYSUNIV, User NMI	015Ah	OFIFG oscillator fault	04h	
		Reserved	06h to 1Eh	Lowest

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6.10.6 Cyclic Redundancy Check (CRC)

The 16-bit cyclic redundancy check (CRC) module produces a signature based on a sequence of data values and can be used for data checking purposes. The CRC generation polynomial is compliant with CRC-16-CCITT standard of $x^{16} + x^{12} + x^5 + 1$.

6.10.7 Enhanced Universal Serial Communication Interface (eUSCI_A0, eUSCI_B0)

The eUSCI modules are used for serial data communications. The eUSCI_A module supports either UART or SPI communications. The eUSCI_B module supports either SPI or I²C communications. Additionally, eUSCI_A supports automatic baud-rate detection and IrDA. The eUSCI_A and eUSCI_B are connected either from P1 port or P2 port, it can be selected from the USCIARMP of SYSCFG3 or USCIBRMP bit of SYSCFG2. Table 6-11 lists the pin configurations that are required for each eUSCI mode.

Table 6-11. eUSCI Pin Configurations

	PIN (USCIARMP = 0)	UART	SPI
	P1.4	TXD	SIMO
	P1.5	RXD	SOMI
	P1.6	-	SCLK
eUSCI_A0	P1.7	ı	STE
eusci_Au	PIN (USCIARMP = 1)	UART	SPI
	P2.0	TXD	SIMO
	P2.1	RXD	SOMI
	P1.6	ı	SCLK
	P1.7	ı	STE
	PIN (USCIBRMP = 0)	I ² C	SPI
	P1.0	ı	STE
	P1.1	ı	SCLK
	P1.2	SDA	SIMO
eUSCI_B0	P1.3	SCL	SOMI
602CI_B0	PIN (USCIBRMP = 1)	I ² C	SPI
	P2.3	1	STE
	P2.4	1	SCLK
	P2.5	SDA	SIMO
	P2.6	SCL	SOMI



6.10.8 Timers (Timer0_A3, Timer1_A3)

The Timer0_A3 and Timer1_A3 modules are 16-bit timers and counters with three capture/compare registers each. Each timer supports multiple captures or compares, PWM outputs, and interval timing (see Figure 6-2). Each timer has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers. The CCR0 registers on both Timer0_A3 and Timer1_A3 are not externally connected and can only be used for hardware period timing and interrupt generation. In Up mode, they can be used to set the overflow value of the counter.

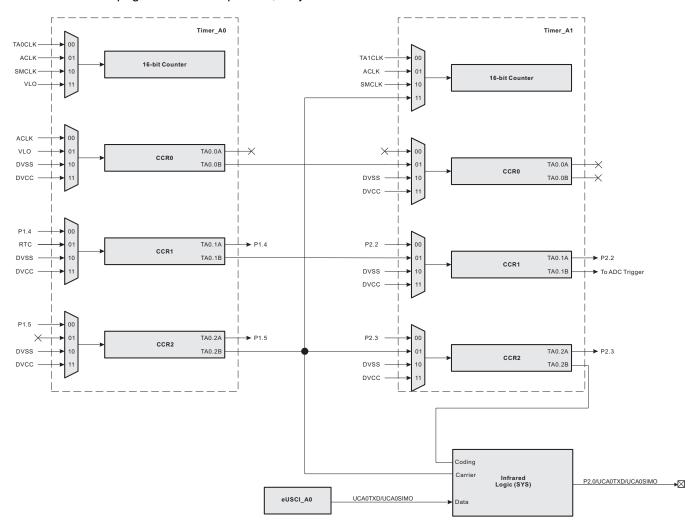


Figure 6-2. Timer0_A3 and Timer1_A3 Signal Connections

The interconnection of Timer0_A3 and Timer1_A3 can be used to modulate the eUSCI_A pin of UCA0TXD/UCA0SIMO in either ASK or FSK mode, with which a user can easily acquire a modulated infrared command for directly driving an external IR diode. The IR functions are fully controlled by SYS configuration registers 1 including IREN (enable), IRPSEL (polarity select), IRMSEL (mode select), IRDSSEL (data select), and IRDATA (data) bits. For more information, see the SYS chapter in the MP430FR4xx and MP430FR2xx Family User's Guide.

6.10.9 Hardware Multiplier (MPY)

The multiplication operation is supported by a dedicated peripheral module. The module performs operations with 32-, 24-, 16-, and 8-bit operands. The MPY module supports signed multiplication, unsigned multiplication, signed multiply-and-accumulate, and unsigned multiply-and-accumulate operations.

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6.10.10 Backup Memory (BAKMEM)

The BAKMEM supports data retention during LPM3.5. This device provides up to 32 bytes that are retained during LPM3.5.

6.10.11 Real-Time Clock (RTC)

The RTC is a 16-bit modulo counter that is functional in AM, LPM0, LPM3, and LPM3.5. This module can periodically wake up the CPU from LPM0, LPM3, or LPM3.5 based on timing from a low-power clock source such as the XT1 and VLO clocks. RTC also can be sourced from ACLK controlled by RTCCLK in SYSCFG2. In AM, RTC can be driven by SMCLK to generate high-frequency timing events and interrupts. The RTC overflow events trigger:

- Timer0 B3 CCI1B
- ADC conversion trigger when ADCSHSx bits are set as 01b

 RTCSS
 CLOCK SOURCE

 00
 Reserved

 01
 SMCLK or ACLK is selected⁽¹⁾

 10
 XT1CLK

 11
 VLOCLK

Table 6-12. RTC Clock Source

(1) Controlled by the RTCCLK bit of the SYSCFG2 register

6.10.12 10-Bit Analog-to-Digital Converter (ADC)

The 10-bit ADC module supports fast 10-bit analog-to-digital conversions with single-ended input. The module implements a 10-bit SAR core, sample select control, a reference generator, and a conversion result buffer. A window comparator with lower and upper limits allows CPU-independent result monitoring with three window comparator interrupt flags.

The ADC supports 10 external inputs and 4 internal inputs (see Table 6-13).

ADCINCHX	ADC CHANNELS	EXTERNAL PIN
0	A0/Veref+	P1.0
1	A1 ⁽¹⁾	P1.1
2	A2/Veref-	P1.2
3	A3	P1.3
4	A4	P2.2
5	A5	P2.3
6	A6	P2.4
7	A7	P2.5
8	Not used	N/A
9	Not used	N/A
10	Not used	N/A
11	Not used	N/A
12	On-chip temperature sensor	N/A
13	Reference voltage (1.5 V)	N/A

Table 6-13. ADC Channel Connections

⁽¹⁾ When A7 is used, the PMM 1.2-V reference voltage can be output to this pin by setting the PMM control register. The 1.2-V voltage can be measured by the A1 channel.

Table 6-13. ADC Channel Connections (continued)

ADCINCHX ADC CHANNELS		EXTERNAL PIN
14 DVSS		N/A
15	DVCC	N/A

The analog-to-digital conversion can be started by software or a hardware trigger. Table 6-14 lists the trigger sources that are available.

Table 6-14. ADC Trigger Signal Connections

ADC	SHSx	TRIGGER SOURCE		
BINARY	DECIMAL	TRIGGER SOURCE		
00	0	ADCSC bit (software trigger)		
01	1	RTC event		
10	2	TA1.1B		
11	3	Reserved		

6.10.13 CapTivate Technology

The CapTIvate module detects the capacitance changed with a charge-transfer method and is functional in AM, LPM0, LPM3 and LPM4. The CapTIvate module can periodically wake the CPU from LPM0, LPM3 or LPM4 based on a CapTIvate timer source such as ACLK or VLO clock. The CapTIvate module also can work on wake-on-touch state machine mode for better power saving without periodically woke up the CPU. The CapTIvate module supports the following touch-sensing capability:

- The MSP430FR2522 supports up to 16 CapTlvate buttons composed of 2 CapTlvate blocks. The MSP430FR2512 supports up to 4 CapTlvate buttons composed of 1 CapTlvate block. Each block consists of 4 I/Os, and these blocks scan in parallel of 2 electrodes.
- Each block can be individually configured in self or mutual mode. Each CapTlvate I/O can be used for either self or mutual electrodes.
- Supports a wake-on-touch state machine.
- Supports synchronized conversion on a zero-crossing event trigger.
- Processing logic to perform filter calculation and threshold detection.

To learn more about MSP MCUs featuring CapTlvate technology, see the CapTlvate™ Technology Guide.

6.10.14 Embedded Emulation Module (EEM)

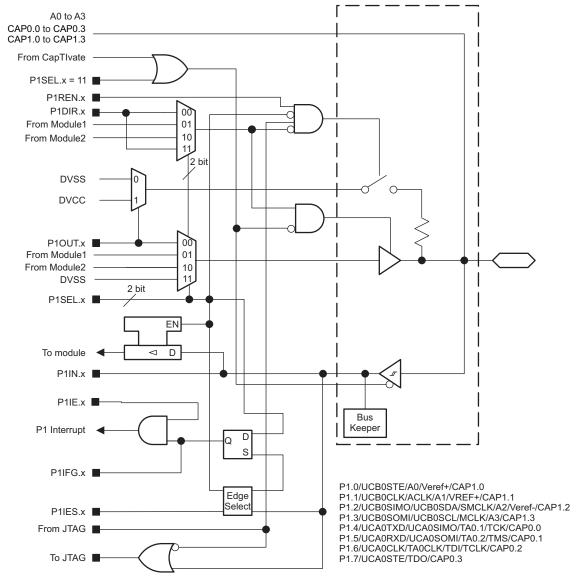
The EEM supports real-time in-system debugging. The EEM on these devices has the following features:

- Three hardware triggers or breakpoints on memory access
- One hardware trigger or breakpoint on CPU register write access
- Up to four hardware triggers can be combined to form complex triggers or breakpoints
- One cycle counter
- Clock control on module level
- EEM version: S

6.11 Input/Output Diagrams

6.11.1 Port P1 (P1.0 to P1.7) Input/Output With Schmitt Trigger

Figure 6-3 shows the port diagram. Table 6-15 summarizes the selection of pin function.



NOTE: CapTIvate channel 1 is available on the MSP430FR2522 only.

Figure 6-3. Port P1 (P1.0 to P1.7) Input/Output With Schmitt Trigger

NOTE

CapTIvate shared with alternative functions

The CapTIvate function and alternative functions are powered by different power supplies (1.5 V and 3.3 V, respectively).

To prevent pad damage when changing the function, TI recommends checking the external application circuit of each pad before enabling the alternative function.



Table 6-15. Port P1 (P1.0 to P1.7) Pin Functions

				CONTROL BITS AND SIGNALS ⁽¹⁾		
PIN NAME (P1.x)	x	FUNCTION	P1DIR.x	P1SELx	ANALOG FUNCTION ⁽²⁾	JTAG
		P1.0 (I/O)	I: 0; O: 1	00	0	N/A
P1.0/UCB0STE/A0/		UCB0STE	X	01	0	N/A
Veref+/CAP1.0 ⁽³⁾	0	A0,Veref+	Х		x = 1 (x = 0) from YSCFG2	N/A
		CAP1.0 ⁽³⁾	X	P1SELx = 11	I, or from CapTIvate	
		P1.1 (I/O)	I: 0; O: 1	00	0	N/A
		UCB0CLK	Х	01	0	N/A
P1.1/UCB0CLK/ACLK/	1	ACLK	1	10	0	N/A
A1/VREF+/CAP1.1 ⁽³⁾	•	A1,VREF+	X		x = 1 (x = 1) from YSCFG2	N/A
		CAP1.1 ⁽³⁾	X	P1SELx = 11	I, or from CapTIvate	
		P1.2 (I/O)	I: 0; O: 1	00	0	N/A
		UCB0SIMO/UCB0SDA	Х	01	0	N/A
P1.2/UCB0SIMO/ UCB0SDA/SMCLK/A2/	2	SMCLK	1	10	0	N/A
Veref-/CAP1.2 ⁽³⁾	_	A2, Veref-	X	ADCPCTLx = 1 (x = 2) from SYSCFG2		N/A
		CAP1.2 ⁽³⁾	X	P1SELx = 11	I, or from CapTIvate	
		P1.3 (I/O)	I: 0; O: 1	00	0	N/A
		UCB0SOMI/UCB0SCL	Х	01	0	N/A
P1.3/UCB0SOMI/ UCB0SCL/MCLK/A3/	3	MCLK	1	10	0	N/A
CAP1.3 ⁽³⁾		А3	Х	ADCPCTLx = 1 (x = 3) from SYSCFG2		N/A
		CAP1.3 ⁽³⁾	Х	P1SELx = 11, or from CapTlvate		
		P1.4 (I/O)	I: 0; O: 1	00	0	Disabled
		UCA0TXD/UCA0SIMO	Х	01	0	Disabled
P1.4/UCA0TXD/	,	TA0.CCI1A	0	40	0	Disabled
UCA0SIMO/TA0.1/ TCK/CAP0.0	4	TA0.1	1	10	0	Disabled
		CAP0.0	X	P1SELx = 11	I, or from CapTIvate	Disabled
		JTAG TCK	Х	Х	Х	TCK
		P1.5 (I/O)	I: 0; O: 1	00	0	Disabled
		UCA0RXD/UCA0SOMI	Х	01	0	Disabled
P1.5/UCA0RXD/ UCA0SOMI/TA0.2/	5	TA0.CCI2A	0	10	0	Disabled
TMS/CAP0.1	5	TA0.2	1	10	0	Disabled
		CAP0.1	X	P1SELx = 11	, or from CapTIvate	Disabled
		JTAG TMS	Х	Х	X	TMS
		P1.6 (I/O)	I: 0; O: 1	00	0	Disabled
P1.6/UCA0CLK/		UCA0CLK	X	01	0	Disabled
TAOCLK/TDI/TCLK/ CAP0.2	6	TA0CLK	0	10	0	Disabled
		CAP0.2	X	P1SELx = 11	, or from CapTIvate	Disabled
		JTAG TDI/TCLK	X	Х	X	TDI/TCLK
		P1.7 (I/O)	I: 0; O: 1	00	0	Disabled
P1.7/UCA0STE/TDO/	7	UCA0STE	X	01	0	Disabled
CAP0.3	'	CAP0.3	X	P1SELx = 11	, or from CapTIvate	Disabled
		JTAG TDO	Х	Х	Х	TDO

⁽¹⁾ X = don't care

⁽²⁾ Setting the bits disables both the output driver and input Schmitt trigger to prevent leakage when analog signals are applied.

³⁾ CapTivate channel 1 is available on the MSP430FR2522 only.

6.11.2 Port P2 (P2.0 to P2.6) Input/Output With Schmitt Trigger

Figure 6-4 shows the port diagram. Table 6-16 summarizes the selection of pin function.

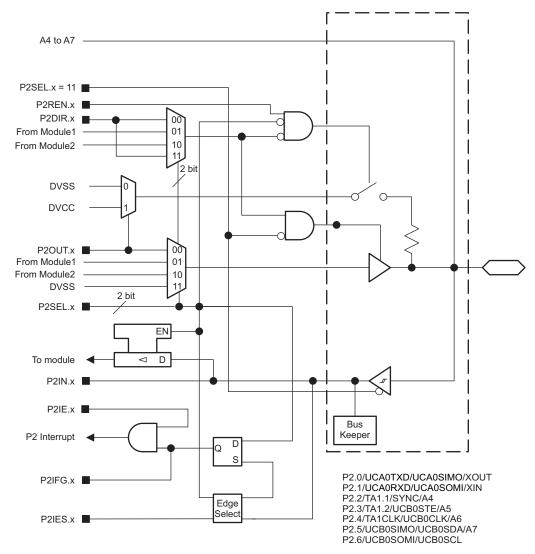


Figure 6-4. Port P2 (P2.0 to P2.6) Input/Output With Schmitt Trigger



Table 6-16. Port P2 (P2.0 to P2.6) Pin Functions

			CONTROL BITS AND SIGNALS ⁽¹⁾		
PIN NAME (P2.x)	x	FUNCTION	P2DIR.x	P2SELx	ANALOG FUNCTION ⁽²⁾
		P2.0 (I/O)	I: 0; O: 1	00	0
P2.0/UCA0TXD/ UCA0SIMO/XOUT	0	UCA0TXD/UCA0SIMO	X	01	0
00/10011110//1001		XOUT	X	10	0
		P2.1 (I/O)	I: 0; O: 1	00	0
P2.1/UCA0RXD/ UCA0SOMI/XIN	1	UCA0RXD/UCA0SOMI	X	01	0
OOAOOOWII/AIIV		XIN	X	10	0
		P2.2 (I/O)	I: 0; O: 1	00	0
		TA1.CCI1A	0	04	0
P2.2/TA1.1/SYNC/A4	2	TA1.1	1	01	0
1 2.2/1A1.1/31NG/A4		SYNC	0	10	0
		A4	х	Х	ADCPCTLx = 1 (x = 4) from SYSCFG2 ⁽²⁾
		P2.3 (I/O)	I: 0; O: 1	00	0
		TA1.CCI2A	0	01	0
P2.3/TA1.2/	3	TA1.2	1		
UCB0STE/A5	3	UCB0STE	Х	10	0
		A5	х	Х	ADCPCTLx = 1 (x = 5) from SYSCFG2 ⁽²⁾
		P2.4 (I/O)	I: 0; O: 1	00	0
DO 4/TA4011//		TA1CLK	0	01	0
P2.4/TA1CLK/ UCB0CLK/A6	4	UCB0CLK	Х	10	0
0000017710		A6	х	Х	ADCPCTLx = 1 (x = 6) from SYSCFG2 ⁽²⁾
P2.5/UCB0SIMO/ UCB0SDA/A7		P2.5 (I/O)	I: 0; O: 1	00	0
	5	UCB0SIMO/UCB0SDA	Х	10	0
		A7	X	Х	ADCPCTLx = 1 (x = 7) from SYSCFG2 ⁽²⁾
P2.6/UCB0SOMI/	_	P2.6 (I/O)	I: 0; O: 1	00	0
UCB0SCL	6	UCB0SOMI/UCB0SCL	Х	10	0

⁽¹⁾ X = don't care

⁽²⁾ Setting the bits disables both the output driver and input Schmitt trigger to prevent leakage when analog signals are applied.

6.12 Device Descriptors

Table 6-17 lists the Device IDs of the devices. Table 6-18 lists the contents of the device descriptor taglength-value (TLV) structure for the devices.

Table 6-17. Device IDs

DEVICE	DEVICE ID	
DEVICE	1A05h	1A04h
MSP430FR2522	83h	10h
MSP430FR2512	83h	1Ch

Table 6-18. Device Descriptors

DECODINE		MSP430FR25x2	
	DESCRIPTION	ADDRESS	VALUE
	Info length	1A00h	06h
	CRC length	1A01h	06h
	CRC value ⁽¹⁾	1A02h	Per unit
of annualis a Disale	CRC value(1)	1A03h	Per unit
nformation Block	D : 1D	1A04h	0 711 047
	Device ID	1A05h	See Table 6-17.
	Hardware revision	1A06h	Per unit
	Firmware revision	1A07h	Per unit
	Die record tag	1A08h	08h
	Die record length	1A09h	0Ah
		1A0Ah	Per unit
	Latination ID	1A0Bh	Per unit
	Lot wafer ID	1A0Ch	Per unit
		1A0Dh	Per unit
Die Record	Die Verselling	1A0Eh	Per unit
	Die X position	1A0Fh	Per unit
	Dia V masitism	1A10h	Per unit
	Die Y position	1A11h	Per unit
	Test result	1A12h	Per unit
	rest result	1A13h	Per unit
	ADC calibration tag	1A14h	Per unit
	ADC calibration length	1A15h	Per unit
	ADC main factor	1A16h	Per unit
	ADC gain factor	1A17h	Per unit
DC solibration	ADC affect	1A18h	Per unit
ADC calibration	ADC offset	1A19h	Per unit
	ADC 4 E V reference, temperature 2000	1A1Ah	Per unit
	ADC 1.5-V reference, temperature 30°C	1A1Bh	Per unit
	ADC 4 E V reference, temperature 95°C	1A1Ch	Per unit
	ADC 1.5-V reference, temperature 85°C	1A1Dh	Per unit

⁽¹⁾ The CRC value covers the check sum from 0x1A04h to 0x1AEFh by applying the CRC-CCITT-16 polynomial of $x^{16} + x^{12} + x^5 + 1$.



Table 6-18. Device Descriptors (continued)

DESCRIPTION		MSP430FR25x2	
		ADDRESS	VALUE
	Calibration tag	1A1Eh	12h
Reference and DCO Calibration Calibration length DCO tap setting for 16 MHz, temperature 30°C ⁽²⁾	Calibration length	1A1Fh	04h
	DCO too cotting for 40 MHz, to one cost up 2000(2)	1A22h	Per unit
	1A23h	Per unit	

⁽²⁾ This value can be directly loaded into DCO bits in CSCTL0 registers to get accurate 16-MHz frequency at room temperature, especially when the MCU exits from LPM3 and below. TI suggests using the predivider to decrease the frequency if the temperature drift might result an overshoot beyond 16 MHz.

6.13 Memory

6.13.1 Memory Organization

Table 6-19 summarizes the memory organization of the devices.

Table 6-19. Memory Organization

	ACCESS	MSP430FR2522 MSP430FR2512
Memory (FRAM) Main: interrupt vectors and signatures Main: code memory	Read/Write (Optional Write Protect) ⁽¹⁾	7.25KB FFFFh to FF80h FFFFh to E300h
RAM	Read/Write	2KB 27FFh to 2000h
Information Memory (FRAM)	Read/Write (Optional Write Protect) ⁽²⁾	256B 18FFh to 1800h
Bootloader (BSL1) Memory (ROM)	Read only	2KB 17FFh to 1000h
Bootloader (BSL2) Memory (ROM)	Read only	1KB FFFFFh to FFC00h
CapTIvate Libraries and Driver Libraries (ROM)	Read only	12KB 6FFFh to 4000h
Peripherals	Read/Write	4KB 0FFFh to 0000h

⁽¹⁾ The Program FRAM can be write protected by setting PFWP bit in SYSCFG0 register. See the SYS chapter in the MP430FR4xx and MP430FR2xx Family User's Guide for more details

⁽²⁾ The Information FRAM can be write protected by setting DFWP bit in SYSCFG0 register. See the SYS chapter in the MP430FR4xx and MP430FR2xx Family User's Guide for more details

6.13.2 Peripheral File Map

Table 6-20 lists the available peripherals and the register base address for each.

Table 6-20. Peripherals Summary

MODULE NAME	BASE ADDRESS	SIZE
Special Functions (See Table 6-21)	0100h	0010h
PMM (See Table 6-22)	0120h	0020h
SYS (See Table 6-23)	0140h	0040h
CS (See Table 6-24)	0180h	0020h
FRAM (See Table 6-25)	01A0h	0010h
CRC (See Table 6-26)	01C0h	0008h
WDT (See Table 6-27)	01CCh	0002h
Port P1, P2 (See Table 6-28)	0200h	0020h
RTC (See Table 6-29)	0300h	0010h
Timer0_A3 (See Table 6-30)	0380h	0030h
Timer1_A3 (See Table 6-31)	03C0h	0030h
MPY32 (See Table 6-32)	04C0h	0030h
eUSCI_A0 (See Table 6-33)	0500h	0020h
eUSCI_B0 (See Table 6-34)	0540h	0030h
Backup Memory (See Table 6-35)	0660h	0020h
ADC (See Table 6-36)	0700h	0040h
CapTIvate (See CapTivate Design Center for details)	0A00h	0200h

Table 6-21. Special Function Registers (Base Address: 0100h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
SFR interrupt enable	SFRIE1	00h
SFR interrupt flag	SFRIFG1	02h
SFR reset pin control	SFRRPCR	04h

Table 6-22. PMM Registers (Base Address: 0120h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
PMM control 0	PMMCTL0	00h
PMM control 1	PMMCTL1	02h
PMM control 2	PMMCTL2	04h
PMM interrupt flags	PMMIFG	0Ah
PM5 control 0	PM5CTL0	10h



Table 6-23. SYS Registers (Base Address: 0140h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
System control	SYSCTL	00h
Bootloader configuration area	SYSBSLC	02h
JTAG mailbox control	SYSJMBC	06h
JTAG mailbox input 0	SYSJMBI0	08h
JTAG mailbox input 1	SYSJMBI1	0Ah
JTAG mailbox output 0	SYSJMBO0	0Ch
JTAG mailbox output 1	SYSJMBO1	0Eh
Bus error vector generator	SYSBERRIV	18h
User NMI vector generator	SYSUNIV	1Ah
System NMI vector generator	SYSSNIV	1Ch
Reset vector generator	SYSRSTIV	1Eh
System configuration 0	SYSCFG0	20h
System configuration 1	SYSCFG1	22h
System configuration 2	SYSCFG2	24h

Table 6-24. CS Registers (Base Address: 0180h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
CS control 0	CSCTL0	00h
CS control 1	CSCTL1	02h
CS control 2	CSCTL2	04h
CS control 3	CSCTL3	06h
CS control 4	CSCTL4	08h
CS control 5	CSCTL5	0Ah
CS control 6	CSCTL6	0Ch
CS control 7	CSCTL7	0Eh
CS control 8	CSCTL8	10h

Table 6-25. FRAM Registers (Base Address: 01A0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
FRAM control 0	FRCTL0	00h
General control 0	GCCTL0	04h
General control 1	GCCTL1	06h

Table 6-26. CRC Registers (Base Address: 01C0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
CRC data input	CRC16DI	00h
CRC data input reverse byte	CRCDIRB	02h
CRC initialization and result	CRCINIRES	04h
CRC result reverse byte	CRCRESR	06h

Table 6-27. WDT Registers (Base Address: 01CCh)

REGISTER DESCRIPTION	ACRONYM	OFFSET
Watchdog timer control	WDTCTL	00h



Table 6-28. Port P1, P2 Registers (Base Address: 0200h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
Port P1 input	P1IN	00h
Port P1 output	P1OUT	02h
Port P1 direction	P1DIR	04h
Port P1 pulling enable	P1REN	06h
Port P1 selection 0	P1SEL0	0Ah
Port P1 selection 1	P1SEL1	0Ch
Port P1 interrupt vector word	P1IV	0Eh
Port P1 interrupt edge select	P1IES	18h
Port P1 complement selection	P1SELC	16h
Port P1 interrupt enable	P1IE	1Ah
Port P1 interrupt flag	P1IFG	1Ch
Port P2 input	P2IN	01h
Port P2 output	P2OUT	03h
Port P2 direction	P2DIR	05h
Port P2 pulling enable	P2REN	07h
Port P2 selection 0	P2SEL0	0Bh
Port P2 selection 1	P2SEL1	0Ch
Port P2 complement selection	P2SELC	17h
Port P2 interrupt vector word	P2IV	1Eh
Port P2 interrupt edge select	P2IES	19h
Port P2 interrupt enable	P2IE	1Bh
Port P2 interrupt flag	P2IFG	1Dh

Table 6-29. RTC Registers (Base Address: 0300h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
RTC control	RTCCTL	00h
RTC interrupt vector	RTCIV	04h
RTC modulo	RTCMOD	08h
RTC counter	RTCCNT	0Ch



Table 6-30. Timer0_A3 Registers (Base Address: 0380h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
TA0 control	TA0CTL	00h
Capture/compare control 0	TA0CCTL0	02h
Capture/compare control 1	TA0CCTL1	04h
Capture/compare control 2	TA0CCTL2	06h
TA0 counter	TA0R	10h
Capture/compare 0	TA0CCR0	12h
Capture/compare 1	TA0CCR1	14h
Capture/compare 2	TA0CCR2	16h
TA0 expansion 0	TA0EX0	20h
TA0 interrupt vector	TAOIV	2Eh

Table 6-31. Timer1_A3 Registers (Base Address: 03C0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
TA1 control	TA1CTL	00h
Capture/compare control 0	TA1CCTL0	02h
Capture/compare control 1	TA1CCTL1	04h
Capture/compare control 2	TA1CCTL2	06h
TA1 counter	TA1R	10h
Capture/compare 0	TA1CCR0	12h
Capture/compare 1	TA1CCR1	14h
Capture/compare 2	TA1CCR2	16h
TA1 expansion 0	TA1EX0	20h
TA1 interrupt vector	TA1IV	2Eh



Table 6-32. MPY32 Registers (Base Address: 04C0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
16-bit operand 1 – multiply	MPY	00h
16-bit operand 1 – signed multiply	MPYS	02h
16-bit operand 1 – multiply accumulate	MAC	04h
16-bit operand 1 – signed multiply accumulate	MACS	06h
16-bit operand 2	OP2	08h
16 x 16 result low word	RESLO	0Ah
16 x 16 result high word	RESHI	0Ch
16 x 16 sum extension	SUMEXT	0Eh
32-bit operand 1 – multiply low word	MPY32L	10h
32-bit operand 1 – multiply high word	MPY32H	12h
32-bit operand 1 – signed multiply low word	MPYS32L	14h
32-bit operand 1 – signed multiply high word	MPYS32H	16h
32-bit operand 1 - multiply accumulate low word	MAC32L	18h
32-bit operand 1 - multiply accumulate high word	MAC32H	1Ah
32-bit operand 1 – signed multiply accumulate low word	MACS32L	1Ch
32-bit operand 1 – signed multiply accumulate high word	MACS32H	1Eh
32-bit operand 2 – low word	OP2L	20h
32-bit operand 2 – high word	OP2H	22h
32 x 32 result 0 – least significant word	RES0	24h
32 x 32 result 1	RES1	26h
32 x 32 result 2	RES2	28h
32 x 32 result 3 – most significant word	RES3	2Ah
MPY32 control 0	MPY32CTL0	2Ch

Table 6-33. eUSCI_A0 Registers (Base Address: 0500h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
eUSCI_A control word 0	UCA0CTLW0	00h
eUSCI_A control word 1	UCA0CTLW1	02h
eUSCI_A control rate 0	UCA0BR0	06h
eUSCI_A control rate 1	UCA0BR1	07h
eUSCI_A modulation control	UCA0MCTLW	08h
eUSCI_A status	UCA0STAT	0Ah
eUSCI_A receive buffer	UCA0RXBUF	0Ch
eUSCI_A transmit buffer	UCA0TXBUF	0Eh
eUSCI_A LIN control	UCA0ABCTL	10h
eUSCI_A IrDA transmit control	IUCA0IRTCTL	12h
eUSCI_A IrDA receive control	IUCA0IRRCTL	13h
eUSCI_A interrupt enable	UCA0IE	1Ah
eUSCI_A interrupt flags	UCA0IFG	1Ch
eUSCI_A interrupt vector word	UCA0IV	1Eh

Table 6-34. eUSCI_B0 Registers (Base Address: 0540h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
eUSCI_B control word 0	UCB0CTLW0	00h
eUSCI_B control word 1	UCB0CTLW1	02h
eUSCI_B bit rate 0	UCB0BR0	06h
eUSCI_B bit rate 1	UCB0BR1	07h



Table 6-34. eUSCI_B0 Registers (Base Address: 0540h) (continued)

REGISTER DESCRIPTION	ACRONYM	OFFSET
eUSCI_B status word	UCB0STATW	08h
eUSCI_B byte counter threshold	UCB0TBCNT	0Ah
eUSCI_B receive buffer	UCB0RXBUF	0Ch
eUSCI_B transmit buffer	UCB0TXBUF	0Eh
eUSCI_B I2C own address 0	UCB0I2COA0	14h
eUSCI_B I2C own address 1	UCB0I2COA1	16h
eUSCI_B I2C own address 2	UCB0I2COA2	18h
eUSCI_B I2C own address 3	UCB0I2COA3	1Ah
eUSCI_B receive address	UCB0ADDRX	1Ch
eUSCI_B address mask	UCB0ADDMASK	1Eh
eUSCI_B I2C slave address	UCB0I2CSA	20h
eUSCI_B interrupt enable	UCB0IE	2Ah
eUSCI_B interrupt flags	UCB0IFG	2Ch
eUSCI_B interrupt vector word	UCB0IV	2Eh



Table 6-35. Backup Memory Registers (Base Address: 0660h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
Backup memory 0	BAKMEM0	00h
Backup memory 1	BAKMEM1	02h
Backup memory 2	BAKMEM2	04h
Backup memory 3	BAKMEM3	06h
Backup memory 4	BAKMEM4	08h
Backup memory 5	BAKMEM5	0Ah
Backup memory 6	BAKMEM6	0Ch
Backup memory 7	BAKMEM7	0Eh
Backup memory 8	BAKMEM8	10h
Backup memory 9	BAKMEM9	12h
Backup memory 10	BAKMEM10	14h
Backup memory 11	BAKMEM11	16h
Backup memory 12	BAKMEM12	18h
Backup memory 13	BAKMEM13	1Ah
Backup memory 14	BAKMEM14	1Ch
Backup memory 15	BAKMEM15	1Eh

Table 6-36. ADC Registers (Base Address: 0700h)

REGISTER DESCRIPTION	REGISTER	OFFSET
ADC control 0	ADCCTL0	00h
ADC control 1	ADCCTL1	02h
ADC control 2	ADCCTL2	04h
ADC window comparator low threshold	ADCLO	06h
ADC window comparator high threshold	ADCHI	08h
ADC memory control 0	ADCMCTL0	0Ah
ADC conversion memory	ADCMEM0	12h
ADC interrupt enable	ADCIE	1Ah
ADC interrupt flags	ADCIFG	1Ch
ADC interrupt vector word	ADCIV	1Eh



6.14 Identification

6.14.1 Revision Identification

The device revision information is included as part of the top-side marking on the device package. The device-specific errata sheet describes these markings.

The hardware revision is also stored in the Device Descriptor structure in the Info Block section. For details on this value, see the Hardware Revision entries in Section 6.12.

6.14.2 Device Identification

The device type can be identified from the top-side marking on the device package. The device-specific errata sheet describes these markings.

A device identification value is also stored in the Device Descriptor structure in the Info Block section. For details on this value, see the Device ID entries in Section 6.12.

6.14.3 JTAG Identification

Programming through the JTAG interface, including reading and identifying the JTAG ID, is described in detail in MSP430 Programming With the JTAG Interface.

7 Applications, Implementation, and Layout

NOTE

Information in the following Applications section is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

7.1 Device Connection and Layout Fundamentals

This section discusses the recommended guidelines when designing with the MSP430 devices. These guidelines are to make sure that the device has proper connections for powering, programming, debugging, and optimum analog performance.

7.1.1 Power Supply Decoupling and Bulk Capacitors

TI recommends connecting a combination of a 10-µF plus a 100-nF low-ESR ceramic decoupling capacitor to the DVCC and DVSS pins. Higher-value capacitors may be used but can impact supply rail ramp-up time. Decoupling capacitors must be placed as close as possible to the pins that they decouple (within a few millimeters). Additionally, TI recommends separated grounds with a single-point connection for better noise isolation from digital-to-analog circuits on the board and to achieve high analog accuracy.

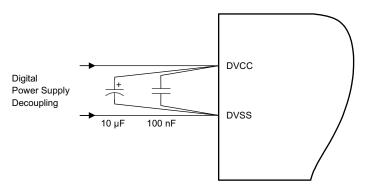


Figure 7-1. Power Supply Decoupling

7.1.2 External Oscillator

This device supports only a low-frequency crystal (32 kHz) on the XIN and XOUT pins. External bypass capacitors for the crystal oscillator pins are required.

It is also possible to apply digital clock signals to the XIN input pin that meet the specifications of the respective oscillator if the appropriate XT1BYPASS mode is selected. In this case, the associated XOUT pin can be used for other purposes. If the XIN and XOUT pins are not used, they must be terminated according to Section 4.6.

Figure 7-2 shows a typical connection diagram.

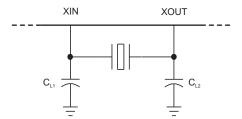


Figure 7-2. Typical Crystal Connection



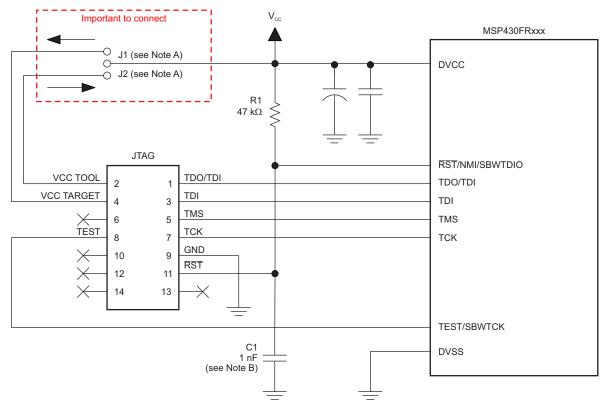
See MSP430 32-kHz Crystal Oscillators for more information on selecting, testing, and designing a crystal oscillator with the MSP430 devices.

7.1.3 JTAG

With the proper connections, the debugger and a hardware JTAG interface (such as the MSP-FET or MSP-FET430UIF) can be used to program and debug code on the target board. In addition, the connections also support the MSP-GANG production programmers, thus providing an easy way to program prototype boards, if desired. Figure 7-3 shows the connections between the 14-pin JTAG connector and the target device required to support in-system programming and debugging for 4-wire JTAG communication. Figure 7-4 shows the connections for 2-wire JTAG mode (Spy-Bi-Wire).

The connections for the MSP-FET and MSP-FET430UIF interface modules and the MSP-GANG are identical. Both can supply V_{CC} to the target board (through pin 2). In addition, the MSP-FET and MSP-FET430UIF interface modules and MSP-GANG have a V_{CC} sense feature that, if used, requires an alternate connection (pin 4 instead of pin 2). The V_{CC} sense feature detects the local V_{CC} present on the target board (that is, a battery or other local power supply) and adjusts the output signals accordingly. Figure 7-3 and Figure 7-4 show a jumper block that supports both scenarios of supplying V_{CC} to the target board. If this flexibility is not required, the desired V_{CC} connections may be hard-wired to eliminate the jumper block. Pins 2 and 4 must not be connected at the same time.

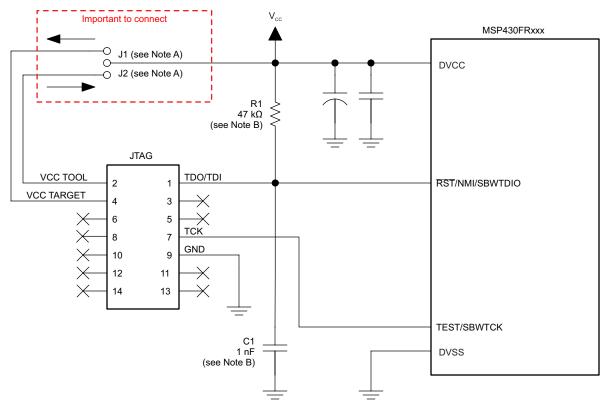
For additional design information regarding the JTAG interface, see the MSP430 Hardware Tools User's Guide.



- A. If a local target power supply is used, make connection J1. If power from the debug or programming adapter is used, make connection J2.
- B. The upper limit for C1 is 1.1 nF when using current TI tools.

Figure 7-3. Signal Connections for 4-Wire JTAG Communication





- A. Make connection J1 if a local target power supply is used, or make connection J2 if the target is powered from the debug or programming adapter.
- The device RST/NMI/SBWTDIO pin is used in 2-wire mode for bidirectional communication with the device during JTAG access, and any capacitance that is attached to this signal may affect the ability to establish a connection with the device. The upper limit for C1 is 1.1 nF when using current TI tools.

Figure 7-4. Signal Connections for 2-Wire JTAG Communication (Spy-Bi-Wire)

7.1.4 Reset

The reset pin can be configured as a reset function (default) or as an NMI function in the Special Function Register (SFR), SFRRPCR.

In reset mode, the RST/NMI pin is active low, and a pulse applied to this pin that meets the reset timing specifications generates a BOR-type device reset.

Setting SYSNMI causes the RST/NMI pin to be configured as an external NMI source. The external NMI is edge sensitive, and its edge is selectable by SYSNMIIES. Setting the NMIIE enables the interrupt of the external NMI. When an external NMI event occurs, the NMIIFG is set.

The RST/NMI pin can have either a pullup or pulldown that is enabled or not. SYSRSTUP selects either pullup or pulldown, and SYSRSTRE causes the pullup (default) or pulldown to be enabled (default) or not. If the RST/NMI pin is unused, it is required either to select and enable the internal pullup or to connect an external 47-kΩ pullup resistor to the RST/NMI pin with a 10-nF pulldown capacitor. The pulldown capacitor should not exceed 1.1 nF when using devices with Spy-Bi-Wire interface in Spy-Bi-Wire mode or in 4-wire JTAG mode with TI tools like FET interfaces or GANG programmers.

See the MP430FR4xx and MP430FR2xx Family User's Guide for more information on the referenced control registers and bits.

7.1.5 Unused Pins

For details on the connection of unused pins, see Section 4.6.

7.1.6 General Layout Recommendations

- Proper grounding and short traces for external crystal to reduce parasitic capacitance. See MSP430 32-kHz Crystal Oscillators for recommended layout guidelines.
- Proper bypass capacitors on DVCC and reference pins, if used.
- Avoid routing any high-frequency signal close to an analog signal line. For example, keep digital switching signals such as PWM or JTAG signals away from the oscillator circuit.
- Proper ESD level protection should be considered to protect the device from unintended high-voltage electrostatic discharge. See MSP430 System-Level ESD Considerations for guidelines.

7.1.7 Do's and Don'ts

During power up, power down, and device operation, DVCC must not exceed the limits specified in Section 5.1. Exceeding the specified limits may cause malfunction of the device including erroneous writes to RAM and FRAM.

7.2 Peripheral- and Interface-Specific Design Information

7.2.1 ADC Peripheral

7.2.1.1 Partial Schematic

Figure 7-5 shows the recommended decoupling circuit when an external voltage reference is used.

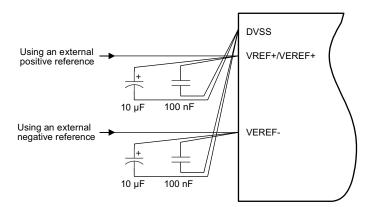


Figure 7-5. ADC Grounding and Noise Considerations

7.2.1.2 Design Requirements

As with any high-resolution ADC, appropriate printed-circuit-board layout and grounding techniques should be followed to eliminate ground loops, unwanted parasitic effects, and noise.

Ground loops are formed when return current from the ADC flows through paths that are common with other analog or digital circuitry. If care is not taken, this current can generate small unwanted offset voltages that can add to or subtract from the reference or input voltages of the ADC. The general quidelines in Section 7.1.1 combined with the connections shown in Figure 7-5 prevent this.

Quickly switching digital signals and noisy power supply lines can corrupt the conversion results, so keep the ADC input trace shielded from those digital and power supply lines. Putting the MCU in low-power mode during the ADC conversion improves the ADC performance in a noisy environment. If the device includes the analog power pair inputs (AVCC and AVSS), TI recommends a noise-free design using separate analog and digital ground planes with a single-point connection to achieve high accuracy.

Figure 7-5 shows the recommended decoupling circuit when an external voltage reference is used. The internal reference module has a maximum drive current as described in the sections *ADC Pin Enable* and 1.2-V Reference Settings of the MSP430FR4xx and MSP430FR2xx Family User's Guide.

The reference voltage must be a stable voltage for accurate measurements. The capacitor values that are selected in the general guidelines filter out the high- and low-frequency ripple before the reference voltage enters the device. In this case, the 10-µF capacitor buffers the reference pin and filters any low-frequency ripple. A bypass capacitor of 100 nF filters out any high-frequency noise.

7.2.1.3 Layout Guidelines

Components that are shown in the partial schematic (see Figure 7-5) should be placed as close as possible to the respective device pins to avoid long traces, because they add additional parasitic capacitance, inductance, and resistance on the signal.

Avoid routing analog input signals close to a high-frequency pin (for example, a high-frequency PWM), because the high-frequency switching can be coupled into the analog signal.

7.2.2 CapTIvate Peripheral

This section provides a brief introduction to the CapTlvate technology with examples of PCB layout and performance from the design kit. A more detailed description of the CapTlvate technology and the tools needed to be successful, application development tools, hardware design guides, and software library, can be found in the CapTlvate™ Technology Guide.

7.2.2.1 Device Connection and Layout Fundamentals

To learn more on how to design the CapTlvate Technology, see the Capacitive Touch Design Flow for MSP430™ MCUs With CapTlvate™ Technology application report.



7.2.2.2 Measurements

The following measurements are taken from the CapTIvate Technology Design Center, using the CAPTIVATE-PHONE and CAPTIVATE-BSWP panels. Unless otherwise stated, the settings used are the out-of-box settings, which can be found in the example projects. The intent of these measurements is to show performance in a configuration that is readily available and reproducible.





Figure 7-6. CAPTIVATE-PHONE and CAPTIVATE-BSWP Panels

7.2.2.2.1 SNR

The Sensitivity, SNR, and Design Margin in Capacitive Touch Applications application report provides a specific view for analyzing the signal-to-noise ratio of each element.

7.2.2.2.2 Sensitivity

To show sensitivity, in terms of farads, the internal reference capacitor is used as the change in capacitance. In the mutual-capacitance case, the 0.1-pF capacitor is used. In the self-capacitance case, the 1-pF reference capacitor is used. For simplicity, the results for only button 1 on both the CAPTIVATE-PHONE and CAPTIVATE-BSWP panels are reported in Table 7-1.

CAPTIVATE-PHONE BUTTON 1 CAPTIVATE-BSWP BUTTON 1 CONVERSION CONVERSION **COUNTS FOR CONVERSION** CONVERSION **COUNTS FOR** COUNT **GAIN** 0.1-pF 1-pF CHANGE TIME (µs) TIME (µs) CHANGE 100 100 25 6 50 8 200 200 50 10 100 16 200 100 50 21 100 31 70 800 400 200 400 112 800 200 200 140 400 202 257 100 200 400 333

Table 7-1. Button Sensitivity

An alternative measure in sensitivity is the ability to resolve capacitance change over a wide range of base capacitance. Table 7-2 shows example conversion times (for a self-mode measurement of discrete capacitors) that can be used to achieve the desired resolution for a given parasitic load capacitance.

Table 7-2. Button Sensitivity

CAPACITANC E Cp (pF) ⁽¹⁾	CONVERSION COUNT/GAIN			COUNTS FOR 0.260-pF CHANGE	COUNTS FOR 0.520-pF CHANGE	
23	400/100	200	10	23	35	
50	550/100	275	11	24	37	
78	650/100	325	11	23	36	
150	850/100	425	11	22	35	
150 ⁽²⁾	1200/200	600	11	23	37	
200(2)	1200/150	600	13	26	41	

⁽¹⁾ These measurements were taken with the CapTlvate MCU processor board with the 470- Ω series resistors replaced with 0- Ω resistors.

7.2.2.2.3 Power

The low-power mode LPM3 and LPM4 specifications in Section 5.7 are derived from the CapTIvate technology design kit as indicated in the notes.

7.3 CapTivate Technology Evaluation

Table 7-3 lists tools that demonstrate the use of the MSP430FR25x2 devices. See CapTIvate Evaluation Tools to get started with evaluating the CapTIvate technology in various real-world application scenarios. Consult these evaluation tool designs for additional guidance regarding schematics, layout, and software implementation.

Table 7-3. Evaluation Tools

DESIGN NAME	LINK
MSP430 CapTlvate™ Touch Keypad BoosterPack Plug-in Module	http://www.ti.com/tool/boostxl-capkeypad

^{(2) 0-}V discharge voltage is used.

8 Device and Documentation Support

8.1 Getting Started and Next Steps

For more information on the MSP low-power microcontrollers and the tools and libraries that are available to help with your development, visit the MSP430™ ultra-low-power sensing & measurement MCUs overview.

8.2 Device Nomenclature

To designate the stages in the product development cycle, TI assigns prefixes to the part numbers of all MSP MCU devices. Each MSP MCU commercial family member has one of two prefixes: MSP or XMS. These prefixes represent evolutionary stages of product development from engineering prototypes (XMS) through fully qualified production devices (MSP).

XMS – Experimental device that is not necessarily representative of the final device's electrical specifications

MSP - Fully qualified production device

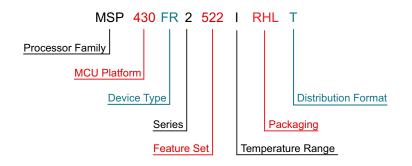
XMS devices are shipped against the following disclaimer:

"Developmental product is intended for internal evaluation purposes."

MSP devices have been characterized fully, and the quality and reliability of the device have been demonstrated fully. Tl's standard warranty applies.

Predictions show that prototype devices (XMS) have a greater failure rate than the standard production devices. TI recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

TI device nomenclature also includes a suffix with the device family name. This suffix indicates the temperature range, package type, and distribution format. Figure 8-1 provides a legend for reading the complete device name.



Processor Family	MSP = Mixed-signal processor XMS = Experimental silicon
MCU Platform	430 = MSP430 16-bit low-power platform
Device Type	FR = FRAM
Series	2 = Up to 16 MHz without LCD
Feature Set	522 = 2 CapTivate blocks, 8KB of FRAM, 2KB of RAM, up to 8 CapTivate I/Os 512 = 1 CapTivate block, 8KB of FRAM, 2KB of RAM, up to 4 CapTivate I/Os
Temperature Range	I = -40°C to 85°C
Packaging	www.ti.com/packaging
Distribution Format	T = Small reel R = Large reel No marking = Tube or tray

Figure 8-1. Device Nomenclature

8.3 Tools and Software

Table 8-1 lists the debug features supported by these microcontrollers. See the *Code Composer Studio IDE for MSP430 MCUs User's Guide* for details on the available features.

Table 8-1. Hardware Features

MSP430 ARCHITECTURE	4-WIRE JTAG	2-WIRE JTAG	BREAK- POINTS (N)	RANGE BREAK- POINTS	CLOCK CONTROL	STATE SEQUENCER	TRACE BUFFER	LPMx.5 DEBUGGING SUPPORT	EEM VERSION
MSP430Xv2	Yes	Yes	3	Yes	Yes	No	No	No	S

Design Kits and Evaluation Modules

MSP-TS430RHL20 20-Pin Target Development Board for MSP430FR2x MCUs

The MSP-TS430RHL20 is a stand-alone ZIF socket target board used to program and debug the MSP430 in-system through the JTAG interface or the Spy Bi-Wire (2-wire JTAG) protocol. The development board supports all MSP430FR252x and MSP430FR242x Flash parts in a 20-pin VQFN package (TI package code: RHL).

MSP-FET + MSP-TS430RHL20 FRAM Microcontroller Development Kit Bundle

The MSP-FET430RHL20-BNDL bundle combines two debugging tools that support the 20-pin RHL package for the MSP430FR2422 microcontroller (for example, MSP430FR2422RHL). These two tools include MSP-TS430RHL20 and MSP-FET.

Software

MSP430Ware™ Software

MSP430Ware software is a collection of code examples, data sheets, and other design resources for all MSP430 devices delivered in a convenient package. In addition to providing a complete collection of existing MSP430 design resources, MSP430Ware software also includes a high-level API called MSP430 Driver Library. This library makes it easy to program MSP430 hardware. MSP430Ware software is available as a component of CCS or as a stand-alone package.

MSP430FR2422 Code Examples

C Code examples are available for every MSP device that configures each of the integrated peripherals for various application needs.

MSP Driver Library

Driver Library's abstracted API keeps you above the bits and bytes of the MSP430 hardware by providing easy-to-use function calls. Thorough documentation is delivered through a helpful API Guide, which includes details on each function call and the recognized parameters. Developers can use Driver Library functions to write complete projects with minimal overhead.

MSP EnergyTrace™ Technology

EnergyTrace technology for MSP430 microcontrollers is an energy-based code analysis tool that measures and displays the application's energy profile and helps to optimize it for ultra-low-power consumption.

ULP (Ultra-Low Power) Advisor

ULP AdvisorTM software is a tool for guiding developers to write more efficient code to fully utilize the unique ultra-low power features of MSP and MSP432 microcontrollers. Aimed at both experienced and new microcontroller developers, ULP Advisor checks your code against a thorough ULP checklist to squeeze every last nano amp out of your application. At build time, ULP Advisor will provide notifications and remarks to highlight areas of your code that can be further optimized for lower power.



FRAM Embedded Software Utilities for MSP Ultra-Low-Power Microcontrollers

The FRAM Utilities is designed to grow as a collection of embedded software utilities that leverage the ultra-low-power and virtually unlimited write endurance of FRAM. The utilities are available for MSP430FRxx FRAM microcontrollers and provide example code to help start application development. Included utilities include Compute Through Power Loss (CTPL). CTPL is utility API set that enables ease of use with LPMx.5 low-power modes and a powerful shutdown mode that allows an application to save and restore critical system components when a power loss is detected.

IEC60730 Software Package

The IEC60730 MSP430 software package was developed to be useful in assisting customers in complying with IEC 60730-1:2010 (Automatic Electrical Controls for Household and Similar Use - Part 1: General Requirements) for up to Class B products, which includes home appliances, arc detectors, power converters, power tools, e-bikes, and many others. The IEC60730 MSP430 software package can be embedded in customer applications running on MSP430s to help simplify the customer's certification efforts of functional safety-compliant consumer devices to IEC 60730-1:2010 Class B.

Fixed Point Math Library for MSP

The MSP IQmath and Qmath Libraries are a collection of highly optimized and high-precision mathematical functions for C programmers to seamlessly port a floating-point algorithm into fixed-point code on MSP430 and MSP432 devices. These routines are typically used in computationally intensive real-time applications where optimal execution speed, high accuracy, and ultra-low energy are critical. By using the IQmath and Qmath libraries, it is possible to achieve execution speeds considerably faster and energy consumption considerably lower than equivalent code written using floating-point math.

Floating Point Math Library for MSP430

Continuing to innovate in the low power and low cost microcontroller space, TI brings you MSPMATHLIB. Leveraging the intelligent peripherals of our devices, this floating point math library of scalar functions brings you up to 26x better performance. Mathlib is easy to integrate into your designs. This library is free and is integrated in both Code Composer Studio and IAR IDEs. Read the user's guide for an in depth look at the math library and relevant benchmarks.

Development Tools

Code Composer Studio™ Integrated Development Environment for MSP Microcontrollers

Code Composer Studio is an integrated development environment (IDE) that supports all MSP microcontroller devices. Code Composer Studio comprises a suite of embedded software utilities used to develop and debug embedded applications. It includes an optimizing C/C++ compiler, source code editor, project build environment, debugger, profiler, and many other features. The intuitive IDE provides a single user interface taking you through each step of the application development flow. Familiar utilities and interfaces allow users to get started faster than ever before. Code Composer Studio combines the advantages of the Eclipse software framework with advanced embedded debug capabilities from TI resulting in a compelling feature-rich development environment for embedded developers. When using CCS with an MSP MCU, a unique and powerful set of plugins and embedded software utilities are made available to fully leverage the MSP microcontroller.

Command-Line Programmer

MSP Flasher is an open-source shell-based interface for programming MSP microcontrollers through a FET programmer or eZ430 using JTAG or Spy-Bi-Wire (SBW) communication. MSP Flasher can download binary files (.txt or .hex) files directly to the MSP microcontroller without an IDE.

MSP MCU Programmer and Debugger

The MSP-FET is a powerful emulation development tool – often called a debug probe – that lets users quickly begin application development on MSP low-power microcontrollers (MCU). Creating MCU software usually requires downloading the resulting binary program to the MSP device for validation and debugging. The MSP-FET provides a debug communication pathway between a host computer and the target MSP. Furthermore, the MSP-FET also provides a backchannel UART connection between the computer's USB interface and the MSP UART. This affords the MSP programmer a convenient method for communicating serially between the MSP and a terminal running on the computer.

MSP-GANG Production Programmer

The MSP Gang Programmer can program up to eight identical MSP430 or MSP432 flash or FRAM devices at the same time. The MSP Gang Programmer connects to a host PC using a standard RS-232 or USB connection and provides flexible programming options that allow the user to fully customize the process. The MSP Gang Programmer is provided with an expansion board, called the Gang Splitter, that implements the interconnections between the MSP Gang Programmer and multiple target devices.

8.4 Documentation Support

The following documents describe the MSP430FR25x2 microcontrollers. Copies of these documents are available on the Internet at www.ti.com.

Receiving Notification of Document Updates

To receive notification of documentation updates—including silicon errata—go to the product folder for your device on ti.com (for example, MSP430FR2522). In the upper right corner, click the "Alert me" button. This registers you to receive a weekly digest of product information that has changed (if any). For change details, check the revision history of any revised document.

Errata

MSP430FR2522 Device Erratasheet

Describes the known exceptions to the functional specifications for all silicon revisions of this device.

MSP430FR2512 Device Erratasheet

Describes the known exceptions to the functional specifications for all silicon revisions of this device.

User's Guides

MSP430FR4xx and MSP430FR2xx Family User's Guide

Detailed description of all modules and peripherals available in this device family.

MSP430 FRAM Device Bootloader (BSL) User's Guide

The BSL can program memory during MSP430 MCU project development and updates. The BSL can be activated by a utility that sends commands using a serial protocol. The BSL enables the user to control the activity of the MSP430 device and to exchange data using a personal computer or other device.

MSP430 Programming With the JTAG Interface

This document describes the functions that are required to erase, program, and verify the memory module of the MSP430 flash-based and FRAM-based microcontroller families using the JTAG communication port. In addition, it describes how to program the JTAG access security fuse that is available on all MSP430 devices. This document describes device access using both the standard 4-wire JTAG interface and the 2-wire JTAG interface, which is also referred to as Spy-Bi-Wire (SBW).

MSP430 Hardware Tools User's Guide

This manual describes the hardware of the TI MSP-FET430 Flash Emulation Tool (FET). The FET is the program development tool for the MSP430 ultra-low-power microcontroller.

Application Reports

MSP430 32-kHz Crystal Oscillators

Selection of the right crystal, correct load circuit, and proper board layout are important for a stable crystal oscillator. This application report summarizes crystal oscillator function and explains the parameters to select the correct crystal for MSP430 ultra-low-power operation. In addition, hints and examples for correct board layout are given. The document also contains detailed information on the possible oscillator tests to ensure stable oscillator operation in mass production.

MSP430 System-Level ESD Considerations

System-level ESD has become increasingly demanding with silicon technology scaling towards lower voltages and the need for designing cost-effective and ultra-low-power components. This application report addresses different ESD topics to help board designers and OEMs understand and design robust system-level designs. A few real-world system-level ESD protection design examples and their results are also discussed.

8.5 Related Links

Table 8-2 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-2. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
MSP430FR2522	Click here	Click here	Click here	Click here	Click here	
MSP430FR2512	Click here	Click here	Click here	Click here	Click here	

8.6 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Community

TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas, and help solve problems with fellow engineers.

TI Embedded Processors Wiki

Texas Instruments Embedded Processors Wiki. Established to help developers get started with embedded processors from Texas Instruments and to foster innovation and growth of general knowledge about the hardware and software surrounding these devices.

8.7 Trademarks

CapTIvate, MSP430, BoosterPack, MSP430Ware, EnergyTrace, ULP Advisor, Code Composer Studio, E2E are trademarks of Texas Instruments.

All other trademarks are the property of their respective owners.



8.8 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.9 Export Control Notice

Recipient agrees to not knowingly export or re-export, directly or indirectly, any product or technical data (as defined by the U.S., EU, and other Export Administration Regulations) including software, or any controlled product restricted by other applicable national regulations, received from disclosing party under nondisclosure obligations (if any), or any direct product of such technology, to any destination to which such export or re-export is restricted or prohibited by U.S. or other applicable laws, without obtaining prior authorization from U.S. Department of Commerce and other competent Government authorities to the extent required by those laws.

8.10 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

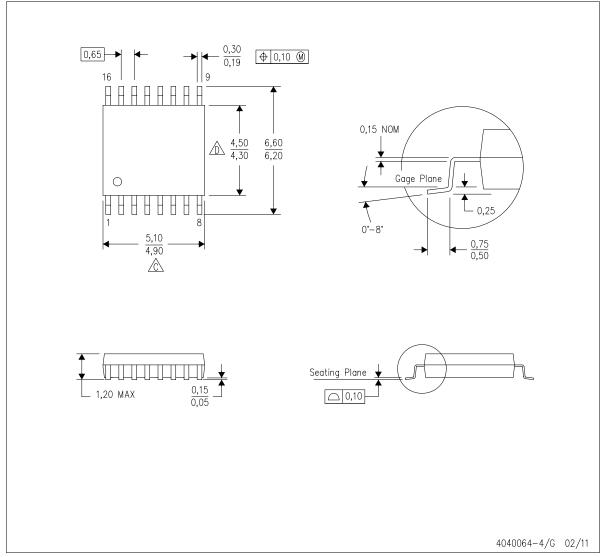
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, see the left-hand navigation.



MECHANICAL DATA

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



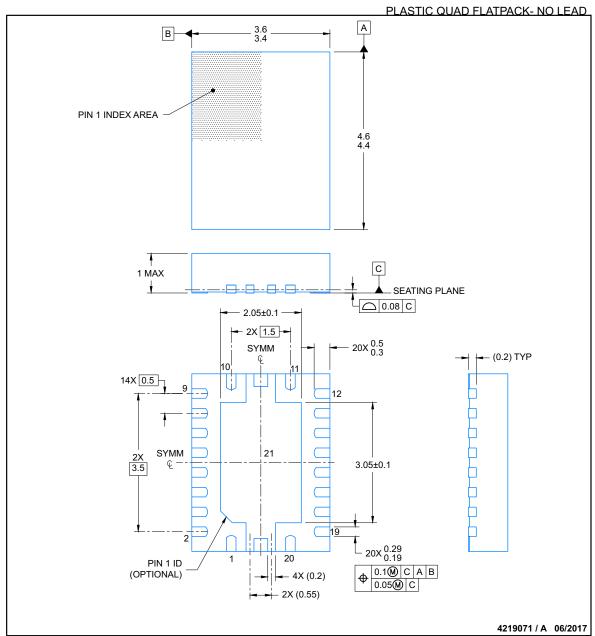
NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153

PACKAGE OUTLINE

RHL 0020A

VQFN - 1 mm max height



NOTES:

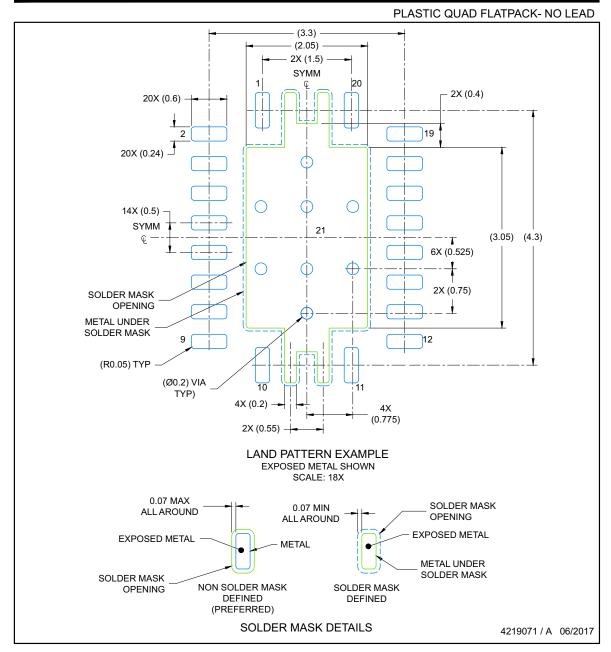
- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



EXAMPLE BOARD LAYOUT

RHL0020A

VQFN - 1 mm max height



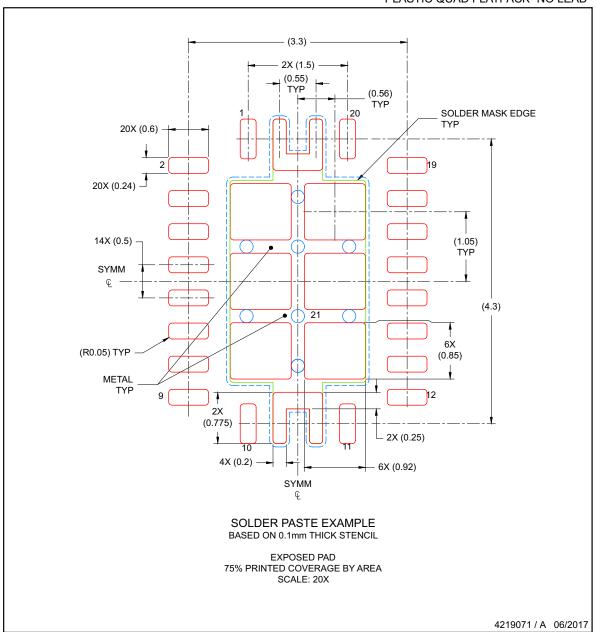
NOTES: (continued)

- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to theri locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN VQFN - 1 mm max height

RHL0020A

PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations..





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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430FR2512IPW16	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2512	Samples
MSP430FR2512IPW16R	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2512	Samples
MSP430FR2512IRHLR	ACTIVE	VQFN	RHL	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2512	Samples
MSP430FR2512IRHLT	ACTIVE	VQFN	RHL	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2512	Samples
MSP430FR2522IPW16	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2522	Samples
MSP430FR2522IPW16R	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2522	Samples
MSP430FR2522IRHLR	ACTIVE	VQFN	RHL	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2522	Samples
MSP430FR2522IRHLT	ACTIVE	VQFN	RHL	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2522	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

25-Jun-2019

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430FR2512IPW16R	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
MSP430FR2512IRHLR	VQFN	RHL	20	3000	330.0	12.4	3.71	4.71	1.1	8.0	12.0	Q1
MSP430FR2512IRHLT	VQFN	RHL	20	250	180.0	12.4	3.71	4.71	1.1	8.0	12.0	Q1
MSP430FR2522IPW16R	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
MSP430FR2522IRHLR	VQFN	RHL	20	3000	330.0	12.4	3.71	4.71	1.1	8.0	12.0	Q1
MSP430FR2522IRHLT	VQFN	RHL	20	250	180.0	12.4	3.71	4.71	1.1	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430FR2512IPW16R	TSSOP	PW	16	2000	350.0	350.0	43.0
MSP430FR2512IRHLR	VQFN	RHL	20	3000	367.0	367.0	35.0
MSP430FR2512IRHLT	VQFN	RHL	20	250	210.0	185.0	35.0
MSP430FR2522IPW16R	TSSOP	PW	16	2000	350.0	350.0	43.0
MSP430FR2522IRHLR	VQFN	RHL	20	3000	367.0	367.0	35.0
MSP430FR2522IRHLT	VQFN	RHL	20	250	210.0	185.0	35.0

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